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HEARING AID COMPATIBILITY

Applicant Name:

Samsung Electronics Co., Ltd. 129, Samsung-ro, Maetan dong, Yeongtong-gu, Suwon-si Gyeonggi-do 16677, Korea

Date of Testing: 10/12/2020 - 11/13/2020 **Test Site/Location:** PCTEST, Columbia, MD, USA **Test Report Serial No.:** 1M2009140143-25-R2.A3L Date of Issue: 11/25/2020

FCC ID: A3LSMG996U

APPLICANT: SAMSUNG ELECTRONICS CO., LTD.

Scope of Test: RF Emissions Testing

Application Type: Certification FCC Rule Part(s): CFR §20.19(b) **HAC Standard:** ANSI C63.19-2011

CTIA Test Plan for Hearing Aid Compatibility Rev 3.1.1, May 2017

285076 D01 HAC Guidance v05

285076 D02 T-Coil testing for CMRS IP v03

DUT Type: Portable Handset Model: SM-G996U Additional Model(s): SM-G996U1

Test Device Serial No.: Pre-Production Sample [S/N: 0516M, 6134M]

C63.19-2011 HAC Category: M3 (RF EMISSIONS CATEGORY)

Note: This revised Test Report (S/N: 1M2009140143-25-R2.A3L) supersedes and replaces the previously issued test report on the same subject device for the same type of testing as indicated. Please discard or destroy the previously issued test report(s) and dispose of it accordingly.

This wireless portable device has been shown to be hearing-aid compatible under the above rated category, specified in ANSI/IEEE Std. C63.19-2011 and has been tested in accordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested. North America bands only.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.









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1. INTRODUCTION

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-86581 to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

Compatibility Tests Involved:

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.



Figure 1-1 Hearing Aid in-vitu

¹ FCC Rule & Order, WT Docket 01-309 RM-8658

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2. DUT DESCRIPTION



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Manufacturer: Samsung Electronics Co., Ltd.

129, Samsung-ro, Maetan dong,

Yeongtong-gu, Suwon-si Gyeonggi-do 16677, Korea

Model: SM-G996U
Additional Model(s): SM-G996U1
Serial Number: 0516M, 6134M
Antenna Configurations: Internal Antenna
DUT Type: Portable Handset

I. Power Reduction for WIFI

This device uses an independent fixed level power reduction mechanism for all WIFI operations during voice or VoIP held to ear scenarios. Reduced powers were used to evaluate for low-power exemption in Section 9.II for WIFI. Detailed descriptions of the power reduction mechanism are included in the operational description.

II. LTE Band Selection

This device supports the following pairs of LTE bands with similar frequencies: LTE B4 & B66 and B38 & B41. Each pair of LTE bands has the same target power and shares the same transmission path. Since the supported frequency spans for the smaller LTE bands are completely covered by the larger LTE bands, only the larger LTE bands (LTE B66 and B41) were evaluated for hearing-aid compliance. LTE B5 and B2 are LTE anchor bands for dual connectivity (EN-DC) scenarios between LTE and NR so they were additionally evaluated as independent LTE bands.

III. NR Band Selection

This device supports the following pair of NR bands with similar frequencies: NR n2 & n25. This pair of NR bands has the same target power and shares the same transmission path. Since the supported frequency span for the smaller NR band is completely covered by the larger NR band, only the larger NR band (NR n25) was evaluated for hearing-aid compliance.

IV. Device Serial Numbers

Several samples with identical hardware were used to support HAC testing. The manufacturer has confirmed that the device(s) tested have the same physical, mechanical, and thermal characteristics are within operational tolerances expected for production units. The serial numbers used for each test are indicated alongside the results in Section 11.

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Table 2-1 A3LSMG996U HAC Air Interfaces

		7.02		U HAC Air interfaces	
Air-Interface	Band (MHz)	Type Transport	HAC Tested	Simultaneous But Not Tested	Name of Voice Service
	835	VO	Yes	Yes: WIFI or BT	CMRS Voice
CDMA	1900				Cimio Voice
	EvDO	VD	No ¹	Yes: WIFI or BT	Google Duo
	850	vo	Yes	Yes: WIFI or BT	CMRS Voice
GSM	1900				cimio voice
	GPRS/EDGE	VD	No ¹	Yes: WIFI or BT	Google Duo
	850				
UMTS	1700	VD	No ¹	Yes: WIFI or BT	CMRS Voice
011110	1900				
	HSPA	VD	No ¹	Yes: WIFI or BT	Google Duo
	680 (B71)		No ^{1 2}		
	700 (B12)				
	780 (B13)				
	790 (B14)				
	850 (B5)				
LTE (FDD)	850 (B26)	VD	No ¹	Yes: WIFI or BT	VoLTE, Google Duo
LIL (100)	1700 (B4)	***			VOLTE, GOOGLE DOO
	1700 (B66)				
	1900 (B2)				
	1900 (B25)				
	2300 (B30)				
	2500 (B7)				
	2600 (B38)				
LTE (TDD)	2600 (B41)	VD	Yes	Yes: WIFI or BT	VoLTE, Google Duo
	3600 (B48)				
	680 (n71)		No ^{1 2}		
	700 (n12)				
	850 (n5)				
NR (FDD)	1700 (n66)	VD	No ¹	Yes: WIFI or BT	Google Duo
	1900 (n2)		NO		
	1900 (n25)				
	2300 (n30)				
	2600 (n41)		Yes		
NR (TDD)	3800 (n77)	VD	163	Yes: WIFI or BT	Google Duo
WK (100)	28000 (n261)	VD	No ³	res. Will of Bi	Google Duo
	39000 (n260)		110		
	2450				
	5200 (U-NII 1)				
WIFI	5300 (U-NII 2A)	VD	No ¹	Yes: CDMA, GSM, UMTS, LTE, or NR	VoWIFI, Google Duo
	5500 (U-NII 2C)				
	5800 (U-NII 3)				
BT	2450	DT	No	Yes: CDMA, GSM, UMTS, LTE, or NR	N/A
-	ype Transport Notes:				rith currently available test

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3. ANSI/IEEE C63.19 PERFORMANCE CATEGORIES

I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters			
Near field Category	E-field emissions CW dB(V/m)			
	f < 960 MHz			
M1	50 to 55			
M2	45 to 50			
M3	40 to 45			
M4	< 40			
	f > 960 MHz			
M1	40 to 45			
M2	35 to 40			
М3	30 to 35			
M4	< 30			
Table 3-1 WD near-field categories as defined in ANSI C63.19-2011				

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4. SYSTEM SPECIFICATIONS

EF3DV3 E-Field Probe Description

Construction: One dipole parallel, two dipoles normal to probe axis

Built-in shielding against static charges

Calibration: In air from 30 MHz to 6.0 GHz

(absolute accuracy ±5.1%, k=2)

Frequency: 30 MHz to > 6 GHz;

Linearity: ± 0.2 dB (30 MHz to 6 GHz)

Directivity $\pm 0.2 \text{ dB}$ in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

Dynamic Range 2 V/m to > 1000 V/m

(M3 or better device readings fall well below diode

compression point)

Linearity: ± 0.2 dB

Dimensions Overall length: 337 mm (Tip: 20 mm)

Tip diameter: 4.0 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 1.5 mm



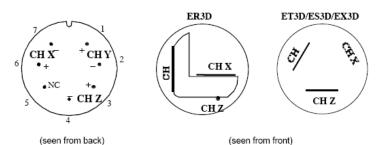
Figure 4-1 E-field Free-space Probe

Probe Tip Description

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

The electric field probes have an irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement").

Connector Plan



The antistatic shielding inside the probe is connected to the probe connector case.

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Equation 1

Conversion of Connector Voltage u, to E-Field E,

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF)/(DCP)}{Norm_i \cdot ConvF}}$$

whereby

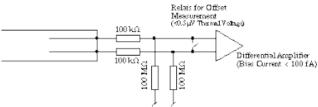
E_i: electric field in V/m

 u_i : voltage of channel i at the connector in μV Norm: sensitivity of channel i in $\mu V/(V/m)^2$ enhancement factor in liquid (ConvF=1 for Air)

DCP: diode compression point in μV

CF: signal crest factor (peak power/average power)

Conditions of Calibration

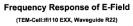


Please note:

- a lower input impedance of the amplifier will result in different sensitivity factors Norm, and DCP
- · larger bias currents will cause higher offset

Probe Response to Frequency

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).



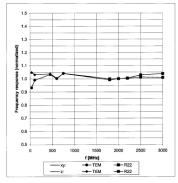


Figure 4-2 E-Field Probe Frequency Response

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SPEAG Robotic System

E-field measurements are performed using the DASY5 automated dosimetric assessment system. The DASY5 is made by Schmid & Partner Engineering AG (SPEAG) in Zurich. Switzerland and consists of high precision robotics system (Staubli), robot controller, Intel CORE i7 computer, near-field probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).



Figure 4-3 SPEAG Robotic System

System Hardware

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the computer with operating system and RF Measurement Software DASY5 v52.8 (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

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System Electronics

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

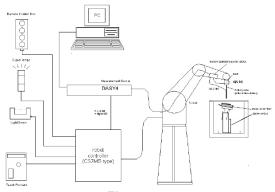


Figure 4-4 SPEAG Robotic System Diagram

DASY5 Instrumentation Chain

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$\begin{aligned} V_i &= U_i + U_i^2 \cdot \frac{cf}{dcp_i} \\ \text{with} \quad V_i &= \text{compensated signal of channel i} & (i = x, y, z) \\ U_i &= \text{input signal of channel i} & (i = x, y, z) \\ cf &= \text{crest factor of exciting field} & (\text{DASY parameter}) \\ dcp_i &= \text{diode compression point} & (\text{DASY parameter}) \end{aligned}$$

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From the compensated input signals the primary field data for each channel can be evaluated:

E – field
probes :
$$E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}}$$

with V_i = compensated signal of channel i (i = x, y, z) $Norm_i$ = sensor sensitivity of channel i (i = x, y, z)

 $\mu V/(V/m)^2$ for E-field Probes

ConvF = sensitivity enhancement in solution

 E_i = electric field strength of channel i in V/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500ms and a probe response time of <5 ms. In the current implementation, DASY5 waits longer than 100ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

Environmental Conditions

Environmental conditions such as temperature and relative humidity are monitored to ensure there are no impacts on system specifications. Proper voltage and power line frequency conditions are maintained with three phase power sources. Environmental noise and reflections are monitored through system checks.

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TEST PROCEDURE 5.

RF EMISSIONS

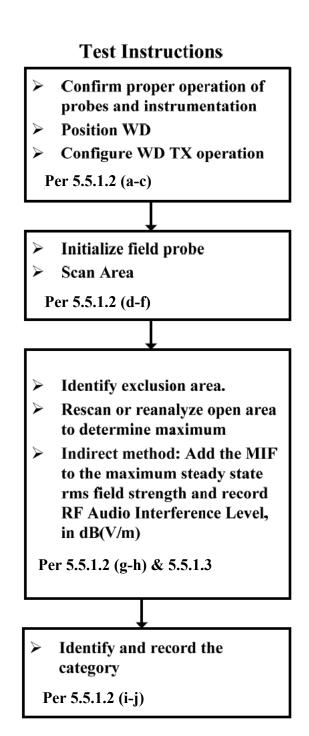


Figure 5-1 RF Emissions Flow Chart

	_			
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Test Setup

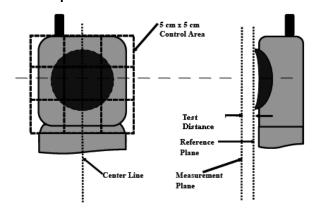


Figure 5-2
E-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)

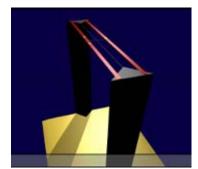


Figure 5-3 HAC Phantom

RF Emissions Test Procedure:

The following illustrate a typical RF emissions test scan over a wireless communications device:

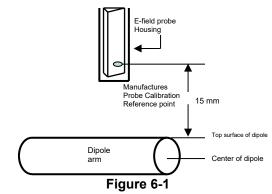
- 1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
- 2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.
- 3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.
- 4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.
- 5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.
- 6. The measurement system measured the field strength at the reference location.
- 7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. Of the 9 subgrids (see Figure 5-2), 3 contiguous subgrids may be excluded from the measurement in order to account for localized areas of higher field intensities. The center subgrid containing the acoustic output or audio band magnetic output may not excluded. A 360° rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.
- 8. The system performed a drift evaluation by measuring the field at the reference location. If the power drift deviated by more than 5%, the HAC test and drift measurements were repeated.

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I. System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 15 mm probe to dipole separation, which is measured from top surface of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is shown in the following diagram:



Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device [e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (20dBm) RMS] after adjustment for any mismatch.

II. Validation Procedure

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

The length of the dipole was scanned, and the average peak value was recorded.

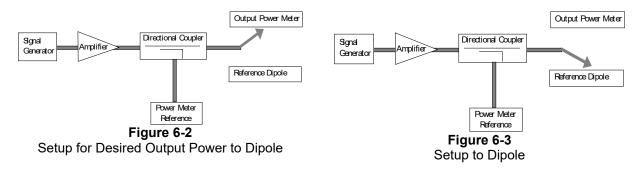
Measurement of CW

Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

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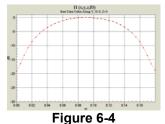
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RF power was recorded using both an average and a peak power reading meter.



Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 6-3.

The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:



2-D Raw Data from scan along dipole axis

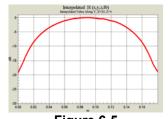
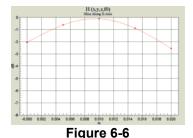
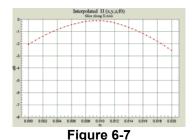


Figure 6-5
2-D Interpolated points from scan along dipole axis



2-D Raw Data from scan along transverse axis



2-D Interpolated points from scan along transverse axis

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III. System Check Results

Validation Results

Date	Frequency (MHz)	Probe S/N	DAE S/N	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation
	835			1003	20.0	105.4	105.2	0.1%
10/12/2020	1880			1137	20.0	92.8	87.8	5.7%
	2600	4035	665	1012	20.0	86.3	85.2	1.2%
11/2/2020	2600			1012	20.0	89.1	85.2	4.6%
11/9/2020	3500			1005	20.0	87.9	84.4	4.2%

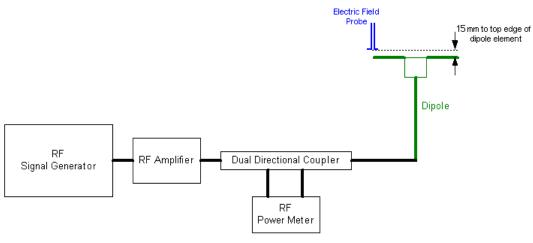


Figure 6-8 System Check Setup

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7. MODULATION INTERFERENCE FACTOR

I. Measuring Modulation Interference Factors

For any specific fixed and repeatable modulated signal, a modulation interference factor (MIF, expressed in dB) may be determined that relates its interference potential to its steady-state RMS signal level or average power level. This factor is a function only of the audio-frequency amplitude modulation characteristics of the signal and is the same for field-strength and conducted power measurements. The MIF is valid only for a specific repeatable audio-frequency amplitude modulation characteristic; any change in modulation characteristic requires determination and application of a new MIF.

The MIF may be determined using a radiated RF field or a conducted RF signal:

- a. Using RF illumination or conducted coupling, apply the specific modulated signal in question to the measurement system at a level within its confirmed operating dynamic range.
- b. Measure the steady-state RMS level at the output of the fast probe or sensor.
- c. Measure the steady-state average level at the weighting output.
- d. Without changing the square-law detector or weighting system, and using RF illumination or conducted coupling, substitute for the specific modulated signal a 1 kHz, 80% amplitude modulated carrier at the same frequency and adjust its strength until the level at the weighting output equals the step c) measurement.
- e. Without changing the carrier level from step d), remove the 1 kHz modulation and again measure the steady-state RMS level indicated at the output of the fast probe or sensor.
- f. The MIF for the specific modulation characteristic is provided by the ratio of the step e) measurement to the step b) measurement, expressed in dB (20 × log[(step e)/(step b)]).

The following procedure was used to measure the MIF using the SPEAG Audio Interference Analyzer (AIA), Type No: SE UMS 170 CB, Serial No.: 1010:

- 1. The device was placed into a simulated call using a base station simulator or set to transmit using test software for a given mode.
- 2. The device was then set to continuously transmit at maximum power.
- 3. Using a coupler if needed, the device output signal was connected to the RF In port of the AIA, which was connected to a desktop computer. Alternatively, a radiated RF signal may be used with the AIA's built-in antenna.
- 4. The MIF measurement procedure in the DASY software was run, and the resulting MIF value was recorded.
- 5. Steps 1-4 were repeated for all CMRS air interfaces, frequency bands, and modulations.

The modulation interference factors obtained were applied to readings taken of the actual wireless device in order to obtain an accurate audio interference level reading using the formula:

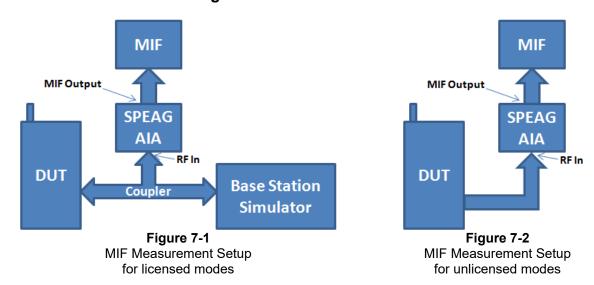
Audio Interference Level [dB(V/m)] = 20 * log[Raw Field Value (V/m)] + MIF (dB)

Because the MIF value is output power independent, MIF values for a given mode should be constant across all devices; however, per C63.19-2011 §D.7, MIF values should be measured for each device being evaluated. The voice modes for this device have been investigated in this section of the report.

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II. MIF Measurement Block Diagrams



III. Measured Modulation Interference Factors:

Table 7-1 CDMA Modulation Interference Factors¹

	ODMA MODULATION INTERFERENCE I ACTORS									
			C	ell	PCS					
Mode		90S	22H	22H	22H	24E	24E	24E		
		564	1013	384	777	25	600	1175		
	RC1/SO3	3.05	3.01	3.09	3.05	3.08	2.97	3.05		
CDMA	RC1/SO55	-19.82	-19.89	-19.91	-19.76	-19.72	-19.66	-19.62		
	EvDO	-19.90	-19.90	-19.82	-19.85	-19.88	-19.70	-19.72		

Table 7-2 **GSM Modulation Interference Factors¹**

Mode			GSM850		GSM1900		
		128	190	251	512	661	810
GSM	Voice	3.54	3.55	3.54	3.55	3.58	3.55
GSIVI	EDGE	3.70	3.69	3.68	3.71	3.72	3.71

Table 7-3 **UMTS Modulation Interference Factors¹**

			UMTS V		UMTS IV				UMTS II	
Mode		4132	4183	4233	1312	1412	1513	9262	9400	9538
	12.2 kbps RMC	-24.14	-23.87	-24.68	-24.81	-24.34	-24.57	-24.89	-24.40	-24.66
UMTS	12.2 kbps AMR	-13.59	-13.15	-13.58	-13.53	-13.63	-13.60	-13.83	-13.87	-13.69
	HSUPA Subtest1	-23.88	-23.49	-23.79	-24.03	-21.67	-22.28	-20.91	-23.27	-21.36

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes

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Table 7-4 LTE FDD Modulation Interference Factors^{1,2,3}

			iteriorenee i	4.010.0			
LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
71	680.5	133297	20	16QAM	1	0	-10.04
12	2 707.5 23095		10	16QAM	1	0	-10.26
13	782.0	23230	10	16QAM	1	0	-9.73
14	793.0	23330	10	16QAM	1	0	-10.56
26	831.5	26865	15	16QAM	1	0	-9.83
5	836.5	20525	10	16QAM	1	0	-9.30
66	1745.0	132322	20	16QAM	1	0	-9.73
2	1880.0	18900	20	16QAM	1	0	-9.67
25	1882.5	26365	20	16QAM	1	0	-9.92
30	2310.0	27710	10	16QAM	1	0	-9.71
7	2535.0	21100	20	16QAM	1	0	-9.61
5	836.5	20525	10	64QAM	1	0	-8.96
5	836.5	20525	10	256QAM	1	0	-8.95
5	836.5	20525	10	QPSK	1	0	-8.97
5	836.5	20525	10	256QAM	1	25	-8.94
5	836.5	20525	10	256QAM	1	49	-9.14
5	836.5	20525	10	256QAM	25	0	-15.59
5			10	256QAM	50	0	-15.68
5	836.5	20525	5	256QAM	1	12	-9.19
5	836.5	20525	3	256QAM	1	7	-9.17
5			1.4	256QAM	1	2	-9.10

Table 7-5 LTE FDD Uplink Carrier Aggregation Modulation Interference Factor^{1,4}

						- 33-	30.0.0								
				PCC				SCC							
Combination	PCC Band	PCC Bandwidth [MHz]	PCC (UL) Channel	PCC (UL) Frequency [MHz]	Modulation	PCC UL# RB	PCC UL RB Offset	SCC Band	SCC Bandwidth [MHz]	SCC (UL) Channel	SCC (UL) Frequency [MHz]	Modulation	SCC UL# RB	SCC UL RB Offset	MIF (dB)
CA_5B	LTE B5	10	20525	836.5	16QAM	1	0	LTE B5	5	20453	829.3	16QAM	1	24	-9.02
CA_66B	LTE B66	10	132322	1745.0	16QAM	1	0	LTE B66	10	132223	1735.1	16QAM	1	49	-9.50
CA_66C	LTE B66	20	132322	1745.0	16QAM	1	0	LTE B66	20	132124	1725.2	16QAM	1	99	-10.19

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

⁴ Note: LTE FDD ULCA was evaluated to ensure LTE FDD standalone was the worst-case scenario. The configurations in Table 7-5 were determined from Table 7-4 and satisfy the configuration requirements as defined in 3GPP 36.101.

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² Note: All FDD LTE bands were found to have substantially similar MIF values given similar RB, BW, and modulation configurations.

³ Note: Since LTE Band 5 at 10MHz bandwidth is the overall worst-case FDD LTE MIF and does not support 3 nonoverlapping channels, MIF measurements were made only on the middle channel.

Table 7-6 LTE TDD B41 Power Class 3 Modulation Interference Factors^{1,2}

			Oldoo O Mic				
LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
41	2593.0	40620	20	16QAM	1	0	1.46
41	41 2593.0 40620		20	QPSK	1	0	1.44
41	2593.0	40620	20	64QAM	1	0	1.56
41	2593.0	40620	20	256QAM	1	0	1.54
41	2593.0	40620	20	64QAM	1	50	1.55
41	2593.0	40620	20	64QAM	1	99	1.54
41	2593.0	40620	20	64QAM	50	0	1.39
41	2593.0	40620	20	64QAM	100	0	1.38
41	2593.0	40620	15	64QAM	1	0	1.43
41	2593.0	40620	10	64QAM	1	0	1.46
41	2593.0	40620	5	64QAM	1	0	1.45
41	2506.0	39750	20	64QAM	1	0	1.54
41	2549.5	40185	20	64QAM	1	0	1.57
41	2636.5	41055	20	64QAM	1	0	1.54
41	2680.0	41490	20	64QAM	1	0	1.55

Table 7-7 LTE TDD B41 Power Class 2 Modulation Interference Factors^{1,2}

П				dalation in			
LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
41	2593.0	40620	20	16QAM	1	0	1.55
41	41 2593.0 40620		20	QPSK	1	0	1.47
41	2593.0	40620	20	64QAM	1	0	1.44
41	2593.0	40620	20	256QAM	1	0	1.44
41	2593.0	40620	20	16QAM	1	50	1.44
41	2593.0	40620	20	16QAM	1	99	1.44
41	2593.0	40620	20	16QAM	50	0	1.43
41	2593.0	40620	20	16QAM	100	0	1.43
41	2593.0	40620	15	16QAM	1	0	1.59
41	2593.0	40620	10	16QAM	1	0	1.61
41	2593.0	40620	5	16QAM	1	0	1.49
41	2506.0	39750	10	16QAM	1	0	1.57
41	2549.5	40185	10	16QAM	1	0	1.47
41	2636.5	41055	10	16QAM	1	0	1.44
41	41 2680.0 4149		10	16QAM	1	0	1.59

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

² Note: LTE TDD MIFs were taken using UL-DL Configuration 2 for both Power Class 3 and Power Class 2. More information about the chosen UL-DL Configuration can be found in Section 10.

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Table 7-8
LTE TDD B48 Modulation Interference Factors^{1,2}

LTE Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Modulation	RB Size	RB Offset	MIF [dB]
48	3625.0	55990	20	16QAM	1	0	1.55
48	3625.0	55990	20	QPSK	1	0	1.48
48	3625.0	55990	20	64QAM	1	0	1.60
48	3625.0	55990	20	256QAM	1	0	1.58
48	3625.0	55990	20	64QAM	1	50	1.56
48	3625.0	55990	20	64QAM	1	99	1.55
48	3625.0	55990	20	64QAM	50	0	1.38
48	3625.0	55990	20	64QAM	100	0	1.39
48	3625.0	55990	15	64QAM	1	0	1.58
48	3625.0	55990	10	64QAM	1	0	1.61
48	3625.0	55990	5	64QAM	1	0	1.40
48	3555.0	55290	10	64QAM	1	0	1.59
48	3695.0	56690	10	64QAM	1	0	1.51

Table 7-9
LTE TDD Uplink Carrier Aggregation Modulation Interference Factor^{1,3}

	PCC										scc				
	PCC							SCC							
Combination	PCC Band	PCC Bandwidth [MHz]	PCC (UL/DL) Channel	PCC (UL/DL) Frequency [MHz]		PCC UL# RB	PCC UL RB Offset	SCC Band	SCC Bandwidth [MHz]	SCC (UL/DL) Channel	SCC (UL/DL) Frequency [MHz]	Modulation	SCC UL# RB	SCC UL RB Offset	MIF (dB)
CA_41C (PC3)	LTE B41	20	40620	2593.0	16QAM	1	0	LTE B41	20	40422	2573.2	16QAM	1	99	1.43
CA_41C (PC2)	LTE B41	20	40620	2593.0	16QAM	1	0	LTE B41	20	40422	2573.2	16QAM	1	99	1.46
CA_48C	LTE B48	20	55773	3603.3	16QAM	1	0	LTE B48	20	55575	3583.5	16QAM	1	99	1.46

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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² Note: LTE TDD MIFs were taken using UL-DL Configuration 2 for Power Class 3 and Power Class 2. More information about the chosen UL-DL Configuration can be found in Section 10.

³ Note: LTE TDD ULCA was evaluated to ensure LTE TDD standalone was the worst-case scenario. The configurations in Table 7-9 were determined from Tables 7-6 through 7-8 and satisfy the configuration requirements as defined in 3GPP 36.101. These MIFs were evaluated with UL-DL Configuration 2 for Power Class 3 and Power Class 2.

Table 7-10

NR FDD Modulation Interference Factors^{1,2,3}

	NR FDD Modulation Interference Factors 12-3													
NR Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Waveform	Modulation	RB Size	RB Offset	MIF [dB]						
n71	680.5	136100	20	DFT-s-OFDM	16QAM	1	1	-9.85						
n12	707.5	141500	15	DFT-s-OFDM	16QAM	1	1	-9.98						
n5	836.5	167300	20	DFT-s-OFDM	16QAM	1	1	-9.56						
n66	1745.0	349000	40	DFT-s-OFDM	16QAM	1	1	-13.14						
n25	1882.5	376500	40	DFT-s-OFDM	16QAM	1	1	-10.76						
n30	2310.0	462000	10	DFT-s-OFDM	16QAM	1	1	-10.74						
n5	836.5	167300	20	DFT-s-OFDM	π/2-BPSK	1	1	-19.93						
n5	836.5	167300	20	DFT-s-OFDM	QPSK	1	1	-15.53						
n5	836.5	167300	20	DFT-s-OFDM	64QAM	1	1	-11.14						
n5	836.5	167300	20	DFT-s-OFDM	256QAM	1	1	-11.19						
n5	836.5	167300	20	CP-OFDM	QPSK	1	1	-11.94						
n5	836.5	167300	20	CP-OFDM	16QAM	1	1	-9.37						
n5	836.5	167300	20	CP-OFDM	64QAM	1	1	-9.35						
n5	836.5	167300	20	CP-OFDM	256QAM	1	1	-10.79						
n5	836.5	167300	20	CP-OFDM	64QAM	1	53	-9.52						
n5	836.5	167300	20	CP-OFDM	64QAM	1	104	-9.24						
n5	836.5	167300	20	CP-OFDM	64QAM	50	0	-17.20						
n5	836.5	167300	20	CP-OFDM	64QAM	100	0	-18.39						
n5	836.5	167300	15	CP-OFDM	64QAM	1	77	-9.39						
n5	836.5	167300	10	CP-OFDM	64QAM	1	50	-9.46						
n5	836.5	167300	5	CP-OFDM	64QAM	1	23	-9.43						

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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² Note: All FDD NR bands were found to have substantially similar MIF values given similar RB, BW, waveform, and modulation configurations.

³ Note: Since NR Band n5 at 20MHz bandwidth is the overall worst-case FDD NR MIF and does not support 3 non-overlapping channels, MIF measurements were made only on the middle channel.

Table 7-11
NR TDD n41 Modulation Interference Factors^{1,2}

	11	יו שטו זו	4 i Wiouui	ation int		1 actors		
NR Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Waveform	Modulation	RB Size	RB Offset	MIF [dB]
n41	2593.0	518598	100	DFT-s-OFDM	π/2-BPSK	1	1	1.38
n41	2593.0	518598	100	DFT-s-OFDM	QPSK	1	1	1.39
n41	2593.0	518598	100	DFT-s-OFDM	16QAM	1	1	1.32
n41	2593.0	518598	100	DFT-s-OFDM	64QAM	1	1	1.26
n41	2593.0	518598	100	DFT-s-OFDM	256QAM	1	1	1.34
n41	2593.0	518598	100	CP-OFDM	QPSK	1	1	1.29
n41	2593.0	518598	100	CP-OFDM	16QAM	1	1	1.33
n41	2593.0	518598	100	CP-OFDM	64QAM	1	1	1.31
n41	2593.0	518598	100	CP-OFDM	256QAM	1	1	1.26
n41	2593.0	518598	100	DFT-s-OFDM	QPSK	1	137	1.38
n41	2593.0	518598	100	DFT-s-OFDM	QPSK	1	271	1.38
n41	2593.0	518598	100	DFT-s-OFDM	QPSK	135	0	1.37
n41	2593.0	518598	100	DFT-s-OFDM	QPSK	270	0	1.38
n41	2541.0	508200	90	DFT-s-OFDM	QPSK	1	1	1.37
n41	2536.0	507204	80	DFT-s-OFDM	QPSK	1	1	1.37
n41	2593.0	518598	60	DFT-s-OFDM	QPSK	1	1	1.36
n41	2593.0	518598	50	DFT-s-OFDM	QPSK	1	1	1.36
n41	2567.3	513468	40	DFT-s-OFDM	QPSK	1	1	1.36
n41	2593.0	518598	30	DFT-s-OFDM	QPSK	1	1	1.35
n41	2593.0	518598	20	DFT-s-OFDM	QPSK	1	1	1.36

Table 7-12

NR TDD n77 Modulation Interference Factors^{1,3}

NR Band	Frequency [MHz]	Channel	Bandwidth [MHz]	Waveform	Modulation	RB Size	RB Offset	MIF [dB]
n77	3750.0	650000	100	DFT-s-OFDM	π/2-BPSK	1	1	1.40
n77	3750.0	650000	100	DFT-s-OFDM	QPSK	1	1	1.34
n77	3750.0	650000	100	DFT-s-OFDM	16QAM	1	1	1.30
n77	3750.0	650000	100	DFT-s-OFDM	64QAM	1	1	1.31
n77	3750.0	650000	100	DFT-s-OFDM	256QAM	1	1	1.33
n77	3750.0	650000	100	CP-OFDM	16QAM	1	1	1.26
n77	3750.0	650000	100	CP-OFDM	QPSK	1	1	1.30
n77	3750.0	650000	100	CP-OFDM	64QAM	1	1	1.34
n77	3750.0	650000	100	CP-OFDM	256QAM	1	1	1.21
n77	3750.0	650000	100	DFT-s-OFDM	π/2-BPSK	1	137	1.36
n77	3750.0	650000	100	DFT-s-OFDM	π/2-BPSK	1	271	1.36
n77	3750.0	650000	100	DFT-s-OFDM	π/2-BPSK	135	0	1.39
n77	3750.0	650000	100	DFT-s-OFDM	π/2-BPSK	270	0	1.39
n77	3750.0	650000	90	DFT-s-OFDM	π/2-BPSK	1	1	1.37
n77	3750.0	650000	80	DFT-s-OFDM	π/2-BPSK	1	1	1.37
n77	3750.0	650000	70	DFT-s-OFDM	π/2-BPSK	1	1	1.36
n77	3750.0	650000	60	DFT-s-OFDM	π/2-BPSK	1	1	1.36
n77	3750.0	650000	50	DFT-s-OFDM	π/2-BPSK	1	1	1.36
n77	3750.0	650000	40	DFT-s-OFDM	π/2-BPSK	1	1	1.37
n77	3750.0	650000	30	DFT-s-OFDM	π/2-BPSK	1	1	1.37
n77	3750.0	650000	20	DFT-s-OFDM	π/2-BPSK	1	1	1.36
n77	3930.0	662000	100	DFT-s-OFDM	π/2-BPSK	1	1	1.38

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

³ Note: Since NR Band n77 at 100MHz bandwidth is the overall worst-case n41 MIF and supports 2, not 3, non-overlapping channels, MIF measurements were made only on the high and low channels.

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² Note: Since NR Band n41 at 100MHz bandwidth is the overall worst-case n41 MIF and does not support 3 non-overlapping channels, MIF measurements were made only on the middle channel.

Table 7-13 802.11b (2.4GHz, SISO) Modulation Interference Factors^{1,2}

Ī	115 (2.40		1b MIF Mea							
	Mode		Data Rate [Mbps]							
		1	1 2 5.5 1							
	802.11b	-10.26	-9.53	-7.29	-6.30					

Table 7-14 802.11g (2.4GHz, SISO) Modulation Interference Factors^{1,2}

802.11g MIF Measurements [dB]											
Mode		Data Rate [Mbps]									
	6	6 9 12 18 24 36 48 54									
802.11g	-7.56										

Table 7-15 802.11g (2.4GHz, MIMO) Modulation Interference Factors^{1,2}

		802.11g MIF Measurements [dB]									
Mode		Data Rate [Mbps]									
	12	12 18 24 36 48 72 92 108									
802.11g	-7.50	-6.71	-6.19	-5.47	-5.02	-4.71	-4.84	-4.99			

Table 7-16 802.11n (2.4GHz, SISO) Modulation Interference Factors^{1,2}

			, ,	a.a.a.a.a.a.a.a.a.a.a.a.a.a.a.a.a.a							
Mode		MCS Index									
	0	1	2	3	4	5	6	7			
802.11n	-7.44	-7.44 -6.15 -5.48 -5.08 -4.79 -4.83 -4.93 -5.04									

Table 7-17 802.11n (2.4GHz, MIMO) Modulation Interference Factors^{1,2}

		8	302.11n (2.	4GHz) MIF	Measuren	nents [dB]					
Mode		MCS Index									
	0 1 2 3 4 5 6 7										
802.11n	-7.35	-7.35 -6.12 -5.38 -4.96 -4.76 -4.76 -4.93 -5.04									

Table 7-18 802.11ax (2.4GHz, SU, SISO) Modulation Interference Factors^{1,2}

	602: 1 tax (2:46112, 66, 6166) infodulation interference i detois										
		20MHz 802.11ax (2.4GHz) MIF Measurements [dB]									
Mode		MCS Index									
	0	0 1 2 3 4 5 6 7 8 9									
802.11ax	-7.01	-5.81	-5.18	-4.89	-4.72	-4.83	-4.91	-5.03	-5.16	-5.29	

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

² Note: WIFI MIF values were found to be independent of the transmit channel.

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Table 7-19 802.11ax (2.4GHz, SU, MIMO) Modulation Interference Factors^{1,2}

	Oddition (2010) and the state of the state o										
		20MHz 802.11ax (2.4GHz) MIF Measurements [dB]									
Mode		MCS Index									
	0	0 1 2 3 4 5 6 7 8 9									
802.11ax	-5.85	-4.90	-4.73	-4.72	-5.09	-5.36	-5.51	-5.53	-5.66	-5.87	

Table 7-20 802.11ax (2.4GHz, RU, SISO) Modulation Interference Factors^{1,2}

ODE: I Tax (E. TOTIZ; IXO, OTOO) INGUALIATION INTERFECTION TOTOTO												
		20MHz 802.11ax (2.4GHz) MIF Measurements [dB]										
Mode		RU Index (MCS Index 04) (GI 1.6us)										
	0	0 8 37 40 53 54 61										
802.11ax	-13.56	-13.19	-12.94	-12.09	-11.70	-11.21	-11.55					

Table 7-21 802.11ax (2.4GHz, RU, MIMO) Modulation Interference Factors^{1,2}

20MHz 802.11ax (2.4GHz) MIF Measurements [dB]											
Mode		RU Index (MCS Index 03) (GI 1.6us)									
	0	0 8 37 40 53 54 61									
802.11ax	-7.47										

Table 7-22 802.11a (5GHz, 20MHz BW, SISO) Modulation Interference Factors^{1,2}

	00 <u>2</u> u	COZITIA (COTIZ) ZOMITIZ BIV, CICO/ MICAGIACION MICOTORICO I ACCORD										
	802.11a MIF Measurements [dB]											
Mode		Data Rate [Mbps]										
	6	6 9 12 18 24 36 48 54										
802.11a	-14.11											

Table 7-23 802.11a (5GHz, 20MHz BW, MIMO) Modulation Interference Factors^{1,2}

	802.11a MIF Measurements [dB]										
Mode		Data Rate [Mbps]									
	12	18	24	36	48	72	92	108			
802.11a	-7.61										

Table 7-24 802.11n (5GHz, 20MHz BW, SISO) Modulation Interference Factors^{1,2}

20MHz BW 802.11n (5GHz) MIF Measurements [dB]												
Mode		MCS Index										
	0	1	2	3	4	5	6	7				
802.11n	-14.04	14.04 -12.90 -12.42 -12.19 -12.41 -12.81 -13.29 -13.40										

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

² Note: WIFI MIF values were found to be independent of the transmit channel.

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Table 7-25 802.11n (5GHz, 20MHz BW, MIMO) Modulation Interference Factors^{1,2}

	20MHz BW 802.11n (5GHz) MIF Measurements [dB]										
Mode		MCS Index									
	0	0 1 2 3 4 5 6 7									
802.11n	-7.45	-6.17	-5.50	-5.06	-4.83	-4.88	-4.98	-5.10			

Table 7-26 802.11ac (5GHz, 20MHz BW, SISO) Modulation Interference Factors^{1,2}

	20MHz BW 802.11ac (5GHz) MIF Measurements [dB]										
Mode		MCS Index									
	0	0 1 2 3 4 5 6 7 8									
802.11ac	-14.21	-13.15	-12.25	-12.10	-12.22	-12.72	-13.07	-13.33	-13.70		

Table 7-27 802.11ac (5GHz. 20MHz BW. MIMO) Modulation Interference Factors^{1,2}

		20MHz BW 802.11ac (5GHz) MIF Measurements [dB]									
Mode	MCS Index										
	0	0 1 2 3 4 5 6 7 8									
802.11ac	-6.17	-6.17 -5.08 -4.77 -4.82 -5.17 -5.56 -5.69 -5.84 -6.09									

Table 7-28 802.11ax (5GHz, 20MHz BW, SU, SISO) Modulation Interference Factors^{1,2}

	602.1 Tax (66112, 2611112 BV), 66, 6166/ Infoadiation Interference Factors											
	20MHz 802.11ax (5GHz) MIF Measurements [dB]											
Mode		MCS Index										
	0	0 1 2 3 4 5 6 7 8 9 10 11										
802.11ax	-13.45	-12.57	-11.99	-12.03	-12.26	-12.84	-13.08	-13.24	-13.58	-14.04	-14.17	-14.37

Table 7-29 802.11ax (5GHz, 20MHz BW, SU, MIMO) Modulation Interference Factors^{1,2}

	ouz. I tax (out iz, zowi iz bvv, ou, willio) modulation interference i actors										
	20MHz 802.11ax (5GHz) MIF Measurements [dB]										
Mode		MCS Index									
	0	0 1 2 3 4 5 6 7 8 9 10 11									
802.11ax	-11.79										

Table 7-30 802.11ax (5GHz, 20MHz BW, RU, SISO) Modulation Interference Factors^{1,2}

	20MHz 802.11ax (5GHz) MIF Measurements [dB]										
Mode		RU Index (MCS Index 02) (GI 1.6us)									
	0	0 8 37 40 53 54 61									
802.11ax	-14.61	-14.69	-13.90	-13.87	-12.83	-12.92	-11.71				

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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² Note: WIFI MIF values were found to be independent of the transmit channel.

Table 7-31 802 11ax (5GHz 20MHz BW RU MIMO) Modulation Interference Factors^{1,2}

002.11	20MHz 802.11ax (5GHz) MIF Measurements [dB]												
Mode RU Index (MCS Index 01) (GI 1.6us)													
	0	8	37	40	53	54	61						
802.11ax	-12.51	-12.51 -12.68 -12.64 -12.62 -11.48 -11.82 -10.78											

Table 7-32 802.11n (5GHz. 40MHz BW. SISO) Modulation Interference Factors^{1,2}

	40MHz BW 802.11n (5GHz) MIF Measurements [dB]										
Mode		MCS Index									
	0	1	2	3	4	5	6	7			
802.11n	-11.81	-11.19	-11.56	-12.06	-13.44	-14.34	-14.81	-15.30			

Table 7-33 802.11n (5GHz, 40MHz BW, MIMO) Modulation Interference Factors^{1,2}

	40MHz BW 802.11n (5GHz) MIF Measurements [dB]											
Mode		MCS Index										
	0	1	2	3	4	5	6	7				
802.11n	-5.84	-4.79	-4.58	-4.69	-5.20	-5.69	-5.87	-6.06				

Table 7-34 802.11ac (5GHz. 40MHz BW. SISO) Modulation Interference Factors^{1,2}

	TOTAL (TOTAL) TOTAL DITT, TOTAL DITTE MEDITAL DITTE MEDITA											
	40MHz BW 802.11ac (5GHz) MIF Measurements [dB]											
Mode		MCS Index										
	0	1	2	3	4	5	6	7	8	9		
802.11ac	-11.78	-10.99	-11.40	-11.93	-13.32	-14.25	-14.63	-15.04	N/A	-16.32		

Table 7-35 802 11ac (5GHz 40MHz RW MIMO) Modulation Interference Factors^{1,2}

	602.11ac (36112, 40M112 BVV, MIMO) Modulation interference 1 actors												
		40MHz BW 802.11ac (5GHz) MIF Measurements [dB]											
Mode		MCS Index											
	0	1	2	3	4	5	6	7	8	9			
802.11ac	-4.81	-4.68	-5.11	-5.55	-6.08	-6.59	-6.75	-6.90	N/A	-7.20			

Table 7-36 802.11ax (5GHz, 40MHz BW, SU, SISO) Modulation Interference Factors^{1,2}

	out it it is the interest of t											
				40N	/Hz 802.11	ax (5GHz)	MIF Measu	urements [dB]			
Mode		MCS Index										
	0	1	2	3	4	5	6	7	8	9	10	11
802.11ax	-11.48	-10.90	-11.03	-11.92	-12.86	-13.97	-14.01	-14.37	-14.60	-14.91	-15.23	-15.70

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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² Note: WIFI MIF values were found to be independent of the transmit channel.

Table 7-37 802.11ax (5GHz, 40MHz BW, SU, MIMO) Modulation Interference Factors^{1,2}

	COLITICAL (COLIE) TORRILL DIV, CO, IMMIC/ MICHAELET MICHIEL L'ACCOLO												
		40MHz 802.11ax (5GHz) MIF Measurements [dB]											
Mode		MCS Index											
	0	1	2	3	4	5	6	7	8	9	10	11	
802.11ax	-10.45	-11.42	-12.26	-13.34	-13.86	-14.58	-14.63	-14.78	-15.63	-15.32	-15.31	-15.26	

Table 7-38 802.11ax (5GHz, 40MHz BW, RU, SISO) Modulation Interference Factors^{1,2}

			40MHz 8	02.11ax (5	GHz) MIF I	Measureme	ents [dB]				
Mode		RU Index (MCS Index 01) (GI 1.6us)									
	0	17	37	44	53	56	61	62	65		
802.11ax	-15.15	-15.21	-14.54	-14.76	-13.55	-13.73	-11.85	-12.06	-10.84		

Table 7-39 802.11ax (5GHz, 40MHz BW, RU, MIMO) Modulation Interference Factors^{1,2}

	40MHz 802.11ax (5GHz) MIF Measurements [dB]											
Mode		RU Index (MCS Index 00) (GI 1.6us)										
	0	17	37	44	53	56	61	62	65			
802.11ax	-13.45	-12.94	-13.48	-13.44	-12.72	-12.65	-11.25	-11.45	-10.37			

Table 7-40 802.11ac (5GHz, 80MHz BW, SISO) Modulation Interference Factors^{1,2}

	COZITIAO (COTIZ) COMITIZ BYT, CICO/ MICAGIACION INCOTICIONO 1 ACCOTO										
	80MHz BW 802.11ac (5GHz) MIF Measurements [dB]										
Mode		MCS Index									
	0	1	2	3	4	5	6	7	8	9	
802.11ac	-11.42	-12.46	-13.67	-14.27	-15.90	-16.80	-16.81	-16.82	-16.90	-17.11	

Table 7-41 802.11ac (5GHz, 80MHz BW, MIMO) Modulation Interference Factors^{1,2}

	delitia (delili, deliti il letti, illilia) illidatation illidate illidate il											
		80MHz BW 802.11ac (5GHz) MIF Measurements [dB]										
Mode		MCS Index										
	0	1	2	3	4	5	6	7	8	9		
802.11ac	-4.73	-5.61	-6.11	-6.51	-6.99	-7.29	-7.30	-7.43	-7.44	-7.62		

Table 7-42 802.11ax (5GHz, 80MHz BW, SU, SISO) Modulation Interference Factors^{1,2}

			•	80N	/Hz 802.11	ax (5GHz)	MIF Measu	rements [dB]			
Mode		MCS Index										
	0 1 2 3 4 5 6 7 8 9 10 1								11			
802.11ax	-11.23	1.23 -12.33 -13.08 -14.05 -14.70 -15.58 -15.66 -15.64 -15.88 -15.75 -16.61 -16.29										

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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² Note: WIFI MIF values were found to be independent of the transmit channel.

Table 7-43 802.11ax (5GHz, 80MHz BW, SU, MIMO) Modulation Interference Factors^{1,2}

	ouzi i iak (ouizi ouini z zii) ou, immo / imodalalion interioroni autoro											
		80MHz 802.11ax (5GHz) MIF Measurements [dB]										
Mode		MCS Index										
	0 1 2 3 4 5 6 7 8 9 10 11								11			
802.11ax	-11.81											

Table 7-44 802.11ax (5GHz, 80MHz BW, RU, SISO) Modulation Interference Factors^{1,2}

	our lax (our la) out the late, it of our land and the late of the late of											
	80MHz 802.11ax (5GHz) MIF Measurements [dB]											
Mode		RU Index (MCS Index 00) (GI 1.6us)										
	0	0 36 37 52 53 60 61 64 65 66 67										
802.11ax	-13.71											

Table 7-45 802.11ax (5GHz. 80MHz BW. RU. MIMO) Modulation Interference Factors^{1,2}

	80MHz 802.11ax (5GHz) MIF Measurements [dB]											
Mode		RU Index (MCS Index 00) (GI 1.6us)										
	0	0 36 37 52 53 60 61 64 65 66 67										
802.11ax	-13.42											

Table 7-46 Simultaneous 2.4GHz and 5GHz WIFI Modulation Interference Factors 1,2,3

Cimulaneous	erence i actors					
# Tx		z WIFI Bm]	2.4 GH [dE		Measured MIF (dB)	
1 X	Ant1 Ant2		Ant1 Ant2			
3	х	x	х	-	-5.76	
3	х	х	•	х	-5.84	
4	х	х	х	х	-5.53	

¹ Note: Measured MIF values may be lower than sample MIF values provided in ANSI C63.19-2011 Annex D.7 Table D.5 due to manufacturing variations for each device, however per Annex D.7, the sample MIF values of Table D.5 are not intended to substitute for measurements of actual devices under test and their respective operating modes.

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² Note: WLAN MIF values were found to be independent of the transmit channel.

³ Note: The configuration for each scenario (e.g. bandwidth, data rate, etc.) was determined using the worst-case configuration from SISO and MIMO MIF measurements.

8. RF CONDUCTED POWER MEASUREMENTS

I. Procedures Used to Establish RF Signal for HAC Testing

The handset was configured to transmit the required air interface in a shielded chamber. Measurements were taken with a fully charged battery.

II. HAC Measurement Conditions

Output Power Verification

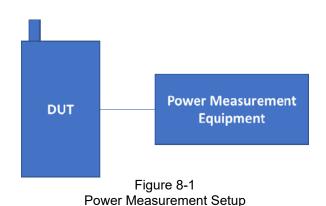
Maximum output power is verified on the High, Middle and Low channels for all applicable air interfaces for which full testing scans are required. Modes which are exempted from full testing according to Section 9 of this report have only their conducted power targets listed below, not measured values. See Table 8-1 for air interface specific settings of transmit power parameters. See Table 9-1 for more information regarding which modes required full testing and had conducted power measurements taken.

Table 8-1
Power Control Parameters and Settings by Air Interface

Air Interface:	Parameter Name:	Parameter Set To:
CDMA	Power Control Bits	"All Up"
GSM	PCL	GSM850: "5"; GSM1900: "0"
UMTS	TPC	"All 1's"
LTE	TPC	"Max Power"
NR	PLS	Mfr Specified
WIFI	PLS	Mfr Specified

III. Setup Used to Measure RF Conducted Powers

The general setup for conducted power is shown in Figure 8-1 below. The power measurement equipment could be a base station simulator, signal analyzer, or power meter depending on the applicable air interface.



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IV. CDMA Conducted Powers

Band	Channel	Rule Part	Frequency	SO2 [dBm]	SO2 [dBm]	SO2 [dBm]	SO55 [dBm]	SO55 [dBm]	SO75 [dBm]	SO9 [dBm]	SO9 [dBm]	SO3 [dBm]	SO3 [dBm]	SO3 [dBm]	1x EvDO Rev. A [dBm]
	F-RC		MHz	RC1	RC3	RC4	RC1	RC3	RC11	RC2	RC5	RC1	RC3	RC4	(RETAP)
Cellular	564	90S	820.1	24.75	24.77	24.76	24.77	24.77	24.80	24.72	24.74	24.74	24.74	24.75	24.82
	1013	22H	824.7	24.43	24.44	24.44	24.43	24.45	24.57	24.45	24.44	24.43	24.42	24.42	24.45
Cellular	384	22H	836.52	24.55	24.53	24.54	24.55	24.55	24.51	24.52	24.53	24.55	24.56	24.54	24.58
	777	22H	848.31	24.45	24.45	24.46	24.43	24.48	24.49	24.48	24.47	24.48	24.49	24.47	24.53
	25	24E	1851.25	23.47	23.46	23.46	23.45	23.47	23.51	23.47	23.48	23.45	23.44	23.47	23.50
PCS	600	24E	1880	23.15	23.15	23.14	23.12	23.13	23.54	23.13	23.14	23.15	23.15	23.12	23.18
	1175	24E	1908.75	23.42	23.45	23.42	23.44	23.44	23.48	23.44	23.42	23.44	23.45	23.41	23.44

V. GSM Conducted Powers

Band	Channel	GSM [dBm] CS (1 Slot)	EDGE [dBm] 1 Tx Slot
	128	32.18	26.51
GSM 850	190	32.36	26.75
	251	32.27	26.52
	512	29.47	25.62
GSM 1900	661	29.15	25.51
	810	29.64	25.57

VI. UMTS Target Powers

Table 8-2 **UMTS Conducted Power Targets**

		M	odulated A	Average (d	lBm)
Mode / Band		3GPP	3GPP	3GPP	3GPP
	WCDMA	HSDPA	HSUPA	DC-HSDPA	
UMTS Band 5 (850 MHz)	Maximum	25.8	24.8	24.8	24.8
UIVITS Ballu 5 (650 IVITIZ)	Nominal	24.8	23.8	23.8	23.8
UMTS Band 4 (1750 MHz)	Maximum	24.5	23.5	23.5	23.5
01V113 Ballu 4 (1730 IVITZ)	Nominal	23.5	22.5	22.5	22.5
UMTS Band 2 (1900 MHz)	Maximum	24.5	23.5	23.5	23.5
UIVITS DATIU 2 (1900 IVITZ)	Nominal	23.5	22.5	22.5	22.5

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VII. LTE FDD Target Powers

Table 8-3 LTE FDD Conducted Power Targets

	Modulated Average	
Mode / Band	l	(dBm)
	Maximum	25.8
LTE Band 71	Nominal	24.8
	Maximum	25.8
LTE Band 12	Nominal	24.8
LTE Band 13	Maximum	25.8
	Nominal	24.8
LTE Band 14	Maximum	25.8
	Nominal	24.8
LTE Band 26 (Cell)	Maximum	25.8
ETE Baria 20 (ecii)	Nominal	24.8
LTE Band 5 (Cell)	Maximum	25.8
LTE Balla 5 (Cell)	Nominal	24.8
LTE David CC (AVAC)	Maximum	24.5
LTE Band 66 (AWS)	Nominal	23.5
LTE David A (ANAIC)	Maximum	24.5
LTE Band 4 (AWS)	Nominal	23.5
LTE D = 12 (DCC)	Maximum	24.5
LTE Band 25 (PCS)	Nominal	23.5
LTE Dand 2 (DCC)	Maximum	24.5
LTE Band 2 (PCS)	Nominal	23.5
LTE Band 30	Maximum	24.0
LIE DAIIU 30	Nominal	23.0
LTE Band 7	Maximum	24.5
LIE Dallu /	Nominal	23.5

Table 8-4
LTE FDD Uplink Carrier Aggregation Conducted Power Targets

Mada / Pana	Modulated Average			
Mode / Band		(dBm)		
LTE Band 5 (Cell)	Maximum	25.8		
LTE Ballu 5 (Cell)	Nominal	24.8		
LTE Dand CC (AVVC)	Maximum	24.5		
LTE Band 66 (AWS)	Nominal	23.5		

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VIII. LTE TDD Target Powers

Table 8-5 LTE TDD Conducted Powers¹

Mode / Band	Modulated Average (dBm)	
LTE Band 48	Maximum	24.5
LIE Dallu 40	Nominal	23.5
LTE Band 41 (PC3)	Maximum	25.0
LIE Ballu 41 (PCS)	Nominal	24.0
LTE Band 41 (PC2)	Maximum	28.0
LIE Ballu 41 (PC2)	Nominal	27.0
LTE Band 38	Maximum	25.0
LIE DAIIU 38	Nominal	24.0

Table 8-6
LTE TDD Uplink Carrier Aggregation Conducted Powers

212 122 Opinik Garrior Aggregation Goridacted Fowere				
Made / Pane	Modulated Average			
Mode / Band		(dBm)		
LTE Band 48	Maximum	24.5		
LIE Ballu 40	Nominal	23.5		
LTE Band 41 (PC3)	Maximum	25.0		
LIE Ballu 41 (PC3)	Nominal	24.0		
LTE Band 41 (PC2)	Maximum	28.0		
LTE Ballu 41 (PC2)	Nominal	27.0		

¹ Conducted power levels were additionally measured to verify operating power levels of configurations used in Tables 11-3 to 11-5.

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IX. NR FDD Target Powers

Table 8-7
NR FDD Conducted Power Targets

ITTE	NR FUD Conducted Power Targets					
Mode / Band	Mode / Band					
Wode, Bane		(dBm)				
NR Band n71	Maximum	25.8				
INN Dallu II/ 1	Nominal	24.8				
NR Band n12	Maximum	25.8				
INN Dallu IIIZ	Nominal	24.8				
NR Band n5	Maximum	25.8				
INN BAHU IIS	Nominal	24.8				
NR Band n66 (Ant A)	Maximum	25.0				
NN Band 1100 (Ant A)	Nominal	24.0				
NR Band n66 (Ant I)	Maximum	24.5				
INN Ballu 1100 (Allt 1)	Nominal	23.5				
NR Band n25 (Ant A)	Maximum	25.3				
INK Ballu 1125 (Allt A)	Nominal	24.3				
ND Dand n2E (Ant I)	Maximum	24.5				
NR Band n25 (Ant I)	Nominal	23.5				
ND Dand n2 (Ant A)	Maximum	25.3				
NR Band n2 (Ant A)	Nominal	24.3				
NP Pand n2 (An+ 1)	Maximum	24.5				
NR Band n2 (Ant I)	Nominal	23.5				
NR Band n30	Maximum	24.0				
INK Dallu 1130	Nominal	23.0				

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X. NR TDD Target Powers

Table 8-8 NR TDD Conducted Powers¹

Mode / Band	Modulated Average (dBm)	
NR Band n41 (PC3, Ant B)	Maximum	25.0
INK Ballu 1141 (PCS, Allt B)	Nominal	24.0
ND Dand n41 (DC2 Ant I)	Maximum	27.0
NR Band n41 (PC2, Ant I)	Nominal	26.0
ND Band 277 (DC2)	Maximum	23.5
NR Band n77 (PC3)	Nominal	22.5
ND Band 277 (DC2)	Maximum	26.5
NR Band n77 (PC2)	Nominal	25.5

¹ Conducted power levels were additionally measured to verify operating power levels of configurations used in Tables 11-6 and 11-7.

XI. WIFI Target Powers (SISO/MIMO)

Table 8-9
IEEE 802.11b/g/n/ax(SU) Reduced Average RF Power Targets¹

		Z. i i brg/ii/	<u>un(00) 1101</u>		802.11 (in d			
Mode Band		SISO			MIMO			
	b	g	n	ax(SU)	g (CDD+STBC)	n (CDD+STBC, SDM)	ax(SU) (CDD+STBC, SDM)	
2.4 GHz WIFI	2.45 GHz	15.0	15.0	15.0	15.0 Ch. 1: 14.5 Ch. 11: 12.5	18.0	18.0	17.0 Ch 1: 14.5 Ch. 2: 15.5 Ch. 10: 15.5 Ch. 11: 12.5

(Upper tolerance: target +1.0dB)

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Table 8-10 IEEE 802.11a/n/ac/ax(SU) Reduced Average RF Power Targets¹

	1222 007	IEEE 802.11 (in dBm)								
Mode	Band	SISO (Antenna 1 and Antenna 2)				мімо				
		а	n	ac	ax (SU)	a (CDD+STBC)	n (CDD+STBC, SDM)	ac (CDD+STBC, SDM)	ax (SU) (CDD+STBC, SDM)	
5 GHz WIFI (20MHz BW)	5200 MHz	12.0	12.0	12.0	12.0	15.0	15.0	15.0	15.0 Ch. 36: 14.5	
	5300 MHz	12.0	12.0	12.0	12.0	15.0	15.0	15.0	15.0 Ch. 64: 14	
	5500 MHz	12.0	12.0	12.0	12.0	15.0	15.0	15.0	15.0	
	5800 MHz	12.0	12.0	12.0	12.0	15.0	15.0	15.0	15.0	
5 GHz WIFI (40MHz BW)	5200 MHz		12.0	12.0	12.0		15.0	15.0	15.0 Ch. 36: 12.5	
	5300 MHz		12.0	12.0	12.0		15.0	15.0	15.0 Ch. 62: 12.5	
	5500 MHz		12.0	12.0	12.0		15.0	15.0	15.0 Ch. 102: 12.5	
	5800 MHz		12.0	12.0	12.0		15.0	15.0	15.0	
5 GHz WIFI (80MHz BW)	5200 MHz			12.0	12.0			15.0	12.0	
	5300 MHz			12.0	11.5			15.0	11.5	
	5500 MHz			12.0	12.0 Ch. 106: 11.5			15.0	15.0 Ch. 106: 11.5	
	5800 MHz			12.0	12.0			15.0	15.0	

(Upper tolerance: target +1.0dB)

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¹ Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

XII. WIFI Target Powers for IEEE 802.11ax RU (SISO/MIMO)

Table 8-11 IEEE 802.11ax (RU) Reduced Average RF Power Targets¹

	incle ober tax (No) Nedadea Average Nr 1 ower targets												
		SISO (AN	Γ1) /in dBm		1	SISO (AN	T2) /in dBm			MIMO (A	LL) /in dBm		
Tones	2.4GHz	5GHz/20MHz	5GHz/40MHz	5GHz/80MHz	2.4GHz	5GHz/20MHz	5GHz/40MHz	5GHz/80MHz	2.4GHz	5GHz/20MHz	5GHz/40MHz	5GHz/80MHz	
26T	13	10	10	10	13	10	10	10	13	10	10	10	
52T	14	12	12	12	14	12	12	12	14	12	12	12	
106T	15 ch 1: 14.0	12	12	12	15 ch 1: 14.0	12	12	12	17 ch 1: 14.0	14	14	14	
	ch 11: 14.0				ch 11: 14.0				ch 11: 14.0				
242T	15 ch 1: 14.5 ch 11: 12.5	12	12	12	15 ch 1: 14.5 ch 11: 12.5	12	12	12	17 Ch 1: 14.5 Ch. 2: 15.5 Ch. 10: 15.5 Ch. 11: 12.5	15 Ch. 36: 14.5 Ch. 64: 14.0	15	15	
484T			12	12			12	12			15 Ch. 38: 12.5 Ch. 62: 12.5 Ch. 102: 12.5	15 Ch. 42: 12.5 Ch. 58: 12.0 Ch. 108: 12.5	
996T				12 Ch. 58: 11.5				12 Ch. 58: 11.5				15 Ch. 42: 12.5 Ch. 58: 11.5 Ch. 106: 12.5	

(Upper tolerance: target +1.0dB)

XIII. WIFI Target Powers for Operations with Simultaneous 2.4GHz and 5GHz

Table 8-12
IEEE 802.11b/g/n/ax(SU) Reduced Average RF Power Targets¹

			<u>(00) 110</u>		802.11 (in d	dBm)		
Mode	Band		SIS	80	MIMO			
		b	g	n	ax(SU)	g (CDD+STBC)	n (CDD+STBC, SDM)	ax(SU) (CDD+STBC, SDM)
2.4 GHz WIFI	2.45 GHz	12.0	12.0	12.0	12.0	15.0	15.0	15.0 Ch. 1: 14.5 Ch. 11: 12.5

(Upper tolerance: target +1.0dB)

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¹ Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

Table 8-13
IEEE 802.11a/n/ac/ax(SU) Reduced Average RF Power Targets¹

			<u> </u>			2.11 (in dBm)	 	
Mode	Band	SISC	O (Antenna 1	and Anten	na 2)		М	IMO	
		а	n	ac	ax (SU)	a (CDD+STBC)	n (CDD+STBC, SDM)	ac (CDD+STBC, SDM)	ax (SU) (CDD+STBC, SDM)
	5200 MHz	12.0	12.0	12.0	12.0	15.0	15.0	15.0	15.0 Ch. 36: 14.5
5 GHz WIFI	5300 MHz	12.0	12.0	12.0	12.0	15.0	15.0	15.0	15.0 Ch. 64: 14
(20MHz BW)	5500 MHz	12.0	12.0	12.0	12.0	15.0	15.0	15.0	15.0
	5800 MHz	12.0	12.0	12.0	12.0	15.0	15.0	15.0	15.0
	5200 MHz		12.0	12.0	12.0		15.0	15.0	15.0 Ch. 36: 12.5
5 GHz WIFI	5300 MHz		12.0	12.0	12.0		15.0	15.0	15.0 Ch. 62: 12.5
(40MHz BW)	5500 MHz		12.0	12.0	12.0		15.0	15.0	15.0 Ch. 102: 12.5
	5800 MHz		12.0	12.0	12.0		15.0	15.0	15.0
	5200 MHz			12.0	12.0			15.0	12.0
5 GHz WIFI	5300 MHz			12.0	11.5			15.0	11.5
(80MHz BW)	5500 MHz			12.0	12.0 Ch. 106: 11.5			15.0	15.0 Ch. 106: 11.5
	5800 MHz			12.0	12.0			15.0	15.0

(Upper tolerance: target +1.0dB)

XIV. WIFI Target Powers for IEEE 802.11ax RU for Operations with Simultaneous 2.4GHz and 5GHz

Table 8-14
IEEE 802.11ax (RU) Reduced Average RF Power Targets¹

	i=== oo=i i ax (i to) i to a a oo a / ti o a ago i a i o i o i a i go to												
			1) /in dBm				T2) /in dBm				LL) /in dBm		
Tones	2.4GHz	5GHz/20MHz	5GHz/40MHz	5GHz/80MHz	2.4GHz	5GHz/20MHz	5GHz/40MHz	5GHz/80MHz	2.4GHz	5GHz/20MHz	5GHz/40MHz	5GHz/80MHz	
26T	12	10	10	10	12	10	10	10	13	10	10	10	
52T	12	12	12	12	12	12	12	12	14	12	12	12	
106T	12	12	12	12	12	12	12	12	15 ch 1: 14.0 ch 11: 14.0	14	14	14	
242T	12	12	12	12	12	12	12	12	15 Ch. 2: 15.5 Ch. 10: 15.5	15 Ch. 36: 14.5 Ch. 64: 14.0	15	15	
484T			12	12			12	12			15 Ch. 38: 12.5 Ch. 62: 12.5 Ch. 102: 12.5	15 Ch. 42: 12.5 Ch. 58: 12.0 Ch. 108: 12.5	
996T				12 Ch. 58: 11.5				12 Ch. 58: 11.5				15 Ch. 42: 12.5 Ch. 58: 11.5 Ch. 108: 12.5	

(Upper tolerance: target +1.0dB)

¹ Note: This device utilizes independent power reduction mechanisms for the WIFI transmitter in all WIFI modes for held-to-ear scenarios.

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9. JUSTIFICATION OF HELD TO EAR MODES TESTED

I. Analysis of RF Air Interface Technologies

An analysis was performed, following the guidance of §4.3 and §4.4 of the ANSI standard, of the RF air interface technologies being evaluated. The factors that will affect the RF interference potential were evaluated, and the worst-case operating modes were identified and used in the evaluation. A WD's interference potential is a function both of the WD's average near-field field strength and of the signal's audio-frequency amplitude modulation characteristics. Per §4.4, RF air interface technologies that have low power have been found to produce sufficiently low RF interference potential, so it is possible to exempt them from the product testing specified in Clause 5 of the ANSI standard. An RF air interface technology of a device is exempt from testing when its average antenna input power plus its MIF is ≤17dBm for all of its operating modes. RF air interface technologies exempted from testing in this manner are automatically assigned an M4 rating to be used in determining the overall rating for the WD.

The worst-case MIF plus the worst-case average antenna input power for all modes are investigated below to determine the testing requirements for this device.

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II. Individual Mode Evaluations

Table 9-1
Max Power + MIF calculations for Low Power Exemptions

Wax 1 GWG1 - Will Calculations for Low 1 GWC1 Exchiptions											
Air Interface	Maximum Average Power (dBm)	Worst Case MIF (dB)	Total (Power + MIF, dB)	C63.19 Testing Required							
CDMA - Full Frame Rate, RC1/SO55	25.50	-19.62	5.88	No							
CDMA - 1/8 th Frame Rate, RC1/SO3	16.47*	3.09	19.56	Yes							
CDMA - EvDO	25.50	-19.70	5.80	No							
GSM - GSM850	24.31*	3.55	27.86	Yes							
GSM - GSM1900	21.31*	3.58	24.89	Yes							
GSM - EDGE850	18.81*	3.70	22.51	Yes†							
GSM - EDGE1900	17.81*	3.72	21.53	Yes†							
UMTS - RMC	25.80	-23.87	1.93	No							
UMTS - AMR	25.80	-13.15	12.65	No							
UMTS - HSPA	24.80	-20.91	3.89	No							
LTE FDD	25.80	-8.94	16.86	No							
LTE FDD - Uplink Carrier Aggregation	25.80	-9.02	16.78	No							
LTE TDD - Band 41 (PC3)	18.31*	1.57	19.88	Yes							
LTE TDD - Band 41 (PC2)	21.31*	1.61	22.92	Yes							
LTE TDD - Band 48	17.81*	1.61	19.42	Yes							
LTE TDD - Uplink Carrier Aggregation	21.31*	1.46	22.77	Yes‡							
NR FDD	25.80	-9.24	16.56	No							
NR TDD - n41 (PC3)	18.98*	1.39	20.37	Yes							
NR TDD - n41 (PC2)	21.28*	1.39	22.67	Yes							
NR TDD - n77 (PC3)	17.48*	1.40	18.88	Yes††							
NR TDD - n77 (PC2)	20.48*	1.40	21.88	Yes							
WIFI - 2.4GHz	18.00	-4.71	13.29	No							
WIFI - 5GHz	15.00	-4.58	10.42	No							
Simultaneous 2.4GHz and 5GHz WIFI Operations	18.01**	-5.53	12.48	No							

^{*} Note: ANSI C63.19-2011 Sec. 4.4 Footnote 20 indicates the use of a long averaging time for measuring the antenna input power when using this method of exclusion. Therefore, the frame averaged power was calculated for these modes in this investigation.

- † Note: EDGE data modes were considered but not tested as GSM voice modes were found to be the worst-case modes for the GSM air interface.
- ‡ Note: LTE TDD Uplink Carrier Aggregation data modes were considered but not tested as LTE TDD standalone modes were found to be the worst-case modes for the LTE TDD air interface.
- †† Note: NR n77 (PC3) was considered but not tested as NR n77 (PC3) and NR n77 (PC2) operate at the same duty cycle and transmit on the same antenna.

III. Low-Power Exemption Conclusions

Per ANSI C63.19-2011, RF Emissions testing for this device is required only for CDMA 1/8th Frame Rate and GSM voice modes as well as LTE TDD (Power Class 3 and Power Class 2) and NR TDD (Power Class 3 and Power Class 2) data modes. All other air interfaces are exempt.

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^{**} Note: This value is calculated as the linear sum of the worst-case power for each band and antenna combination while in simultaneous 2.4GHz and 5GHz operation. This calculation is conservative and for use in this investigation only.

10. LTE TDD UPLINK-DOWNLINK CONFIGURATION

I. Uplink-Downlink Configuration Additional Testing

Additional testing was performed on each supported power class for LTE TDD to determine the worst-case Uplink-Downlink configuration for RFE testing.

Per 3GPP TS 36.211, the total frame length for each TDD radio frame of length T_f = 307200 · T_s = 10 ms, where T_s is a number of time units equal to 1/(15000 x 2048) seconds. Additionally, each radio frame consists of 10 subframes, each of length $30720 \cdot T_s$ = 1 ms, and subframes can be designated as uplink (U), downlink (D), or special subframe (S), depending on the Uplink-Downlink configuration as indicated in Table 4.2-2 of 3GPP TS 36.211. In the transmission duty factor calculation, the special subframe configuration with the shortest UpPTS duration within the special subframe is used and will be applied for measurement. From 3GPP TS 36.211 Table 4.2-1, the shortest UpPTS is 2192 · Ts which occurs in the normal cyclic prefix and special subframe configuration 4.

See table below outlining the calculated transmission duty cycles for each Uplink-Downlink configuration:

Table 10-1Uplink-Downlink Configurations for Type 2 Frame Structures

Uplink-downlink configuration	Downlink-to-Uplink Switch-point periodicity	Subframe number										Calculated Transmission
configuration	Switch-point periodicity	0	1	2	3	4	5	6	7	8	9	Duty Cycle (%)
0	5 ms	D	S	U	U	U	D	S	U	U	U	61.4%
1	5 ms	D	S	U	U	D	D	S	U	U	D	41.4%
2	5 ms	D	S	U	D	D	D	S	U	D	D	21.4%
3	10 ms	D	S	U	U	U	D	D	D	D	D	30.7%
4	10 ms	D	S	U	U	D	D	D	D	D	D	20.7%
5	10 ms	D	S	U	D	D	D	D	D	D	D	10.7%
6	5 ms	D	S	U	U	U	D	S	U	U	D	51.4%

II. Power Class 3 Uplink-Downlink Configuration Additional Testing

LTE TDD was evaluated with the following radio configuration: channel 40620, 20MHz BW, 16QAM, 1RB, 0RB Offset. For Power Class 3, all configurations (0-6) are supported. The configuration which resulted in the worst-case emission was used for full testing. See Table 10-2 below for results. The configuration determined in the results below was used to measure the MIF values in Tables 7-6 and 7-8.

Table 10-2LTE TDD Power Class 3 UL-DL Configuration Results

					טטי		roi oide	000	DL 001	mgarac	0111103	aito			
Mode / Band	Bandwidth (MHz)	Channel	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	E-Field Emissions														
	20	40620	0	16QAM	1	0	Acoustic	11.00	20.83	-3.32	17.51	35.00	-17.49	M4	2,3,6
	20	40620	1	16QAM	1	0	Acoustic	9.56	19.61	-1.56	18.05	35.00	-16.95	M4	2,3,6
	20	40620	2	16QAM	1	0	Acoustic	7.02	16.93	1.50	18.43	35.00	-16.57	M4	2,3,6
LTE TDD / Band 41	20	40620	3	16QAM	1	0	Acoustic	8.49	18.58	-1.48	17.10	35.00	-17.90	M4	2,3,6
	20	40620	4	16QAM	1	0	Acoustic	7.03	16.94	0.70	17.64	35.00	-17.36	M4	2,3,6
	20	40620	5	16QAM	1	0	Acoustic	5.29	14.46	3.73	18.19	35.00	-16.81	M4	2,3,6
	20	40620	6	16QAM	1	0	Acoustic	10.12	20.10	-2.52	17.58	35.00	-17.42	M4	2,3,6

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III. Power Class 2 Uplink-Downlink Configuration Additional Testing

LTE TDD was evaluated with the following radio configuration: channel 40620, 20MHz BW, 16QAM, 1RB, 0RB Offset. For Power Class 2, only configurations 1-5 are supported. The configuration which resulted in the worst-case emission was used for full testing. See Table 10-3 below for results. The configuration determined in the results below was used to measure the MIF values in Table 7-7.

Table 10-3LTE TDD Power Class 2 UL-DL Configuration Results

			_							5					
Mode / Band	Bandwidth (MHz)	Channel	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons														
	20	40620	1	16QAM	1	0	Acoustic	10.04	20.03	-1.56	18.47	35.00	-16.53	M4	2,3,6
	20	40620	2	16QAM	1	0	Acoustic	9.16	19.24	1.55	20.79	35.00	-14.21	M4	1,2,3
LTE TDD / Band 41	20	40620	3	16QAM	1	0	Acoustic	11.72	21.38	-1.47	19.91	35.00	-15.09	M4	1,2,3
	20	40620	4	16QAM	1	0	Acoustic	9.17	19.25	0.74	19.99	35.00	-15.01	M4	2,3,6
	20	40620	5	16QAM	1	0	Acoustic	6.74	16.57	3.86	20.43	35.00	-14.57	M4	2,3,6

IV. Conclusion

Per the results above, UL-DL Configuration 2 was used for both LTE TDD Power Class 3 and LTE TDD Power Class 2 testing.

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11. OVERALL MEASUREMENT SUMMARY

FCC ID:	A3LSMG996U
S/N:	0516M, 6134M

I. E-FIELD EMISSIONS:

Table 11-1 HAC Data Summary for CDMA F-field

	(dBm) (V/m) [dB(V/m)] (dB) Level (dBV/m) (dB) per 5.5												
Mode	Channel	RC/SO	DUT SN	Scan Center	Power at BS	Field	Field		Interference Level			Result	
E-Field Emission	ons												
	564*	RC1/SO3	0516M	Acoustic	24.74	11.94	21.54	3.05	24.59	45.00	-20.41	M4	7,8,9
Cellular CDMA	1013	RC1/SO3	0516M	Acoustic	24.43	11.76	21.41	3.01	24.42	45.00	-20.58	M4	7,8,9
Cellular CDMA	384	RC1/SO3	0516M	Acoustic	24.55	7.89	17.94	3.09	21.03	45.00	-23.97	M4	7,8,9
	777	RC1/SO3	0516M	Acoustic	24.48	10.19	20.16	3.05	23.21	45.00	-21.79	M4	7,8,9
	25	RC1/SO3	0516M	Acoustic	23.45	5.52	14.84	3.08	17.92	35.00	-17.08	M4	1,2,3
PCS CDMA	600	RC1/SO3	0516M	Acoustic	23.15	5.27	14.44	2.97	17.41	35.00	-17.59	M4	1,2,3
	1175	RC1/SO3	0516M	Acoustic	23.44	5.55	14.89	3.05	17.94	35.00	-17.06	M4	1,2,3

*Note: Cell. CDMA Ch. 564 is the Part 90S test channel.

Table 11-2 HAC Data Summary for GSM E-field

					ata Guii	illiai y iv		L-IICIG				
Mode	Channel	DUT SN	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons											
	128	0516M	Acoustic	32.18	29.25	29.32	3.54	32.86	45.00	-12.14	M4	7,8,9
GSM850	190	0516M	Acoustic	32.36	16.60	24.40	3.55	27.95	45.00	-17.05	M4	7,8,9
	251	0516M	Acoustic	32.27	21.96	26.83	3.54	30.37	45.00	-14.63	M4	7,8,9
	512	0516M	Acoustic	29.47	10.39	20.33	3.55	23.88	35.00	-11.12	M4	1,2,3
GSM1900	661	0516M	Acoustic	29.15	9.58	19.63	3.58	23.21	35.00	-11.79	M4	1,2,3
	810	0516M	Acoustic	29.64	9.73	19.76	3.55	23.31	35.00	-11.69	M4	1,2,3

Table 11-3 HAC Data Summary for LTE TDD B41 (PC3) E-field

Mode / Band	Bandwidth (MHz)	Channel	DUT SN	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons																
	20	39750	0516M	2	64QAM	1	0	Acoustic	22.01	6.38	16.10	1.54	17.64	35.00	-17.36	M4	1,2,3
	20	40185	0516M	2	64QAM	1	0	Acoustic	21.93	5.54	14.87	1.57	16.44	35.00	-18.56	M4	1,2,3
LTE TDD / Band 41 PC3	20	40620	0516M	2	64QAM	1	0	Acoustic	21.54	6.23	15.89	1.56	17.45	35.00	-17.55	M4	2,3,6
	20	41055	0516M	2	64QAM	1	0	Acoustic	21.72	6.58	16.36	1.54	17.90	35.00	-17.10	M4	2,3,6
	20	41490	0516M	2	64QAM	1	0	Acoustic	21.59	6.36	16.07	1.55	17.62	35.00	-17.38	M4	2,3,6

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Table 11-4 HAC Data Summary for LTE TDD B41 (PC2) E-field

											,	,					
Mode / Band	Bandwidth (MHz)	Channel	DUT SN	UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons																
	10	39750	0516M	2	16QAM	1	0	Acoustic	25.94	8.43	18.52	1.57	20.09	35.00	-14.91	M4	2,3,6
	10	40185	0516M	2	16QAM	1	0	Acoustic	25.53	8.85	18.94	1.47	20.41	35.00	-14.59	M4	2,3,6
LTE TDD / Band 41 PC2	10	40620	0516M	2	16QAM	1	0	Acoustic	26.36	8.86	18.95	1.61	20.56	35.00	-14.44	M4	1,2,3
	10	41055	0516M	2	16QAM	1	0	Acoustic	25.55	9.43	19.49	1.44	20.93	35.00	-14.07	M4	2,3,6
	10	41490	0516M	2	16QAM	1	0	Acoustic	26.46	9.01	19.09	1.59	20.68	35.00	-14.32	M4	2,3,6

Table 11-5 HAC Data Summary for LTE TDD B48 E-field

Mode / Band	Bandwidth (MHz)	Channel		UL-DL Config.	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons																
	10	55290	6134M	2	64QAM	1	0	Acoustic	21.62	8.51	18.60	1.59	20.19	35.00	-14.81	M4	7,8,9
LTE TDD / Band 48	10	55990	6134M	2	64QAM	1	0	Acoustic	21.90	9.75	19.78	1.61	21.39	35.00	-13.61	M4	7,8,9
	10	56690	6134M	2	64QAM	1	0	Acoustic	21.66	10.22	20.19	1.51	21.70	35.00	-13.30	M4	7,8,9

Table 11-6 HAC Data Summary for NR TDD n41 E-field

Mode / Band	Bandwidth (MHz)	Channel	DUT SN	Antenna	Waveform	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emission	ons																	
	100	518598	0516M	Ant B - PC3	DFT-s-OFDM	QPSK	1	1	Acoustic	23.49	8.50	18.59	1.39	19.98	35.00	-15.02	M4	2,3,6
NR TDD / n41	100	518598	0516M	Ant I - PC2	DFT-s-OFDM	QPSK	1	1	Acoustic	26.25	37.98	31.59	1.39	32.98	35.00	-2.02	M3	1,2,4
	100	518598	0516M	Ant I - PC2	DFT-s-OFDM	QPSK	1	1	T-Coil	26.25	36.20	31.17	1.39	32.56	35.00	-2.44	M3	6,8,9

Table 11-7 HAC Data Summary for NR TDD n77 E-field

									. •				-				
Mode / Band	Bandwidth (MHz)	Channel	DUT SN	Waveform	Mod.	RB Size	RB Offset	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
E-Field Emissi	ons																
NR TDD / n77	100	650000	6134M	DFT-s-OFDM	π/2-BPSK	1	1	Acoustic	24.39	18.18	25.19	1.40	26.59	35.00	-8.41	M4	7,8,9
NK IDD/II//	100	662000	6134M	DFT-s-OFDM	π/2-BPSK	1	1	Acoustic	25.04	17.73	24.97	1.38	26.35	35.00	-8.65	M4	7,8,9

II. Worst-case Configuration Evaluation

Table 11-8 Peak Reading 360° Probe Rotation at Azimuth axis

Mode	Bandwidth (MHz)	Channel	DUT SN	Battery Cover	Waveform	Mod.	RB Size	RB Offset	Scan Center	Time Avg. Field (V/m)	Time Avg. Field [dB(V/m)]	MIF (dB)	Audio Interference Level [dB(V/m)]	FCC Limit (dBV/m)	FCC Margin (dB)	Result	Excl Blocks per 5.5
Probe Rotation	n at Worst-Case																
NR TDD / n41	100	518598	0516M	Ant I - PC2	DFT-s-OFDM	QPSK	1	1	Acoustic	39.38	31.90	1.36	33.26	35.00	-1.74	M3	1,2,4

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Figure 11-1 Sample E-field Scan Overlay (See Test Setup Photographs for actual WD overlay)

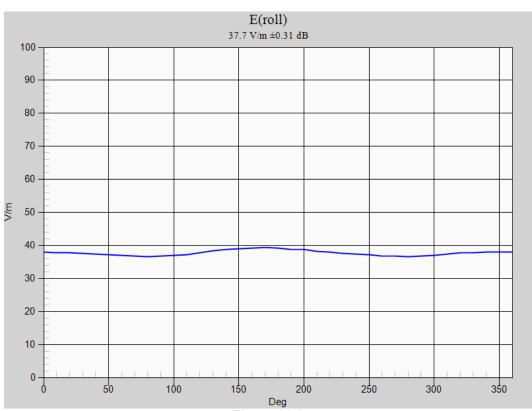


Figure 11-2 **Worst-Case Probe Rotation about Azimuth axis**

* Note: Locations of probe rotation (with and without exclusions) are shown in Figure 11-1 denoted by the green square markers.

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12. EQUIPMENT LIST

Table 12-1 Equipment List

Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
Agilent	E4438C	ESG Vector Signal Generator	8/10/2020	Annual	8/10/2021	MY47270002
Agilent	N5182A	MXG Vector Signal Generator	5/13/2020	Annual	5/13/2021	MY47420603
Amplifier Research	15S1G6	Amplifier	N/A	N/A	N/A	433978
Anritsu	ML2496A	Power Meter	3/23/2020	Annual	3/23/2021	1351001
Anritsu	MA2411B	Pulse Power Sensor	7/28/2020	Annual	7/28/2021	1339018
Anritsu	MA2411B	Pulse Power Sensor	8/12/2020	Annual	8/12/2021	1207364
Anritsu	MA24106A	USB Power Sensor	7/24/2020	Annual	7/24/2021	1344556
Anritsu	MA24106A	USB Power Sensor	7/24/2020	Annual	7/24/2021	1349514
Mini-Circuits	NLP-1200+	Low Pass Filter DC to 1000 MHz	N/A	N/A	N/A	N/A
Mini-Circuits	NLP-2950+	Low Pass Filter DC to 2700 MHz	N/A	N/A	N/A	N/A
Mini-Circuits	BW-N20W5	Power Attenuator	N/A	N/A	N/A	1226
Pasternack	PE2237-20	Bidirectional Coupler	N/A	N/A	N/A	N/A
Rohde & Schwarz	CMW500	Radio Communication Tester	5/21/2020	Annual	5/21/2021	128635
Rohde & Schwarz	CMW500	Wideband Radio Communication Tester	2/4/2020	Annual	2/4/2021	162125
Rohde & Schwarz	CMW500	Radio Communication tester	9/4/2020	Annual	9/4/2021	140144
Seekonk	NC-100	Torque Wrench (8" lb)	8/4/2020	Biennial	8/4/2022	21053
SPEAG	AIA	Audio Interference Analzyer	N/A	N/A	N/A	1010
SPEAG	DAE4	Dasy Data Acquisition Electronics	2/12/2020	Annual	2/12/2021	665
SPEAG	CD1880V3	Freespace 1880 MHz Dipole	2/19/2019	Biennial	2/19/2021	1137
SPEAG	CD2600V3	Freespace 2600MHz Dipole	2/19/2019	Biennial	2/19/2021	1012
SPEAG	CD835V3	Freespace 835 MHz Dipole	2/19/2019	Biennial	2/19/2021	1003
SPEAG	EF3DV3	Freespace E-field Probe	1/16/2020	Annual	1/16/2021	4035
SPEAG	CD3500V3	Freespace 3500 MHz Dipole	10/20/2020	Biennial	10/20/2022	1005

Calibration traceable to the National Institute of Standards and Technology (NIST).

*Note: CBT (Calibrated Before Testing). Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

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13. MEASUREMENT UNCERTAINTY

Table 13-1 Uncertainty Estimation Table

		Communication	ns Device Ne	ear-Field Me			
Uncertainty Component	Data	Data Type	Prob. Dist.	Divisor	Ci (E)	Unc. (dB)	Notes/Comments
	(dB)	,,				, ,	
Measurement System	0.50	- .		1.00		0.50	+ D (I - 00 ID
RF System Reflections	0.50	Tolerance	N	1.00	1	0.50	* Refl. < -20 dB
Field Probe Calibration	0.21	Tolerance	N	1.00	1	0.21	
Field Probe Isotropy	0.01	Tolerance	N	1.00	1	0.01	
Field Probe Frequency Response	0.135	Tolerance	N	1.00	1	0.14	
Field Probe Linearity	0.013	Tolerance	N	1.00	1	0.01	
Modulation Interference Factor	0.20	Tolerance	R	1.73	1	0.12	Applicable for M-rating testing
Boundary Effects	0.105	Accuracy	R	1.73	1	0.06	*
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.12	*
Probe Positioner	0.050	Accuracy	R	1.73	1	0.03	*
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	0.03	*
Resolution to 2mm error	0.21	Tolerance	N	1.00	1	0.21	
System Detection Limit	0.05	Tolerance	R	1.73	1	0.03	*
Readout Electronics	0.015	Tolerance	N	1.00	1	0.02	*
Integration Time	0.11	Tolerance	R	1.73	1	0.06	*
Response Time	0.033	Tolerance	R	1.73	1	0.02	*
Phantom Thickness	0.10	Tolerance	R	1.73	1	0.06	*
System Repeatability (Field x 2=power)	0.17	Tolerance	N	1.00	1	0.17	*
Test Sample Related							
Device Positioning Vertical	0.2	Tolerance	R	1.73	1	0.12	*
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	0.03	*
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	0.06	*
Power Drift	0.21	Tolerance	R	1.73	1	0.12	
Combined Standard Uncertainty (k=1)						0.66	16.3%
Expanded Uncertainty [95% confidence]					1.31	32.6%	
Expanded Uncertainty [95% confidence]	on Field					0.66	16.3%

Notes:

- Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All
 equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81
 and NIST Tech Note 1297 and UKAS M3003.
- 2. * Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurement uncertainty. Another component of the overall uncertainty is based on the variability of repeated measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurement results with that of the instrumentation chain using the technique contained in NIS 81 and NIS 3003, the overall measurement uncertainty was estimated.

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14. TEST DATA

See following Attached Pages for Test Data.

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DUT: CD835V3 - SN1003

Type: CD835V3 Serial: 1003

Communication System: CW; Frequency: 835 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

835 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x361x1):

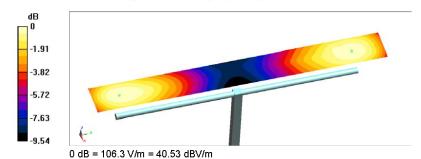
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 129.8 V/m; Power Drift = 0.09 dB

Applied MIF = 0.00 dB

Average Value of Peak (interpolated) = 105.4 V/m



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DUT: CD1880V3 - SN1137

Type: CD1880V3 Serial: 1137

Communication System: CW; Frequency: 1880 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

1880 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

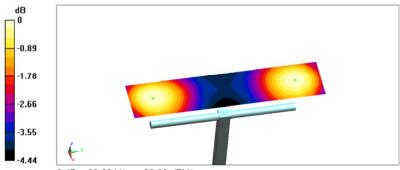
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 162.6 V/m; Power Drift = -0.01 dB

Applied MIF = 0.00 dB

Average Value of Peak (interpolated) = 92.8 V/m



0 dB = 93.09 V/m = 39.38 dBV/m

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DUT: CD2600V3 - SN1012

Type: CD2600V3 Serial: 1012

Communication System: CW; Frequency: 2600 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

2600 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

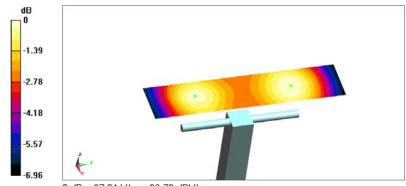
Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 67.43 V/m; Power Drift = 0.07 dB

Applied MIF = 0.00 dB

Average Value of Peak (interpolated) = 86.3 V/m



0 dB = 87.01 V/m = 38.79 dBV/m

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DUT: CD2600V3 - SN1012

Type: CD2600V3 Serial: 1012

Communication System: CW; Frequency: 2600 MHz;

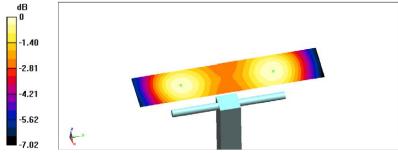
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- · Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

2600 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 68.89 V/m; Power Drift = 0.05 dB Applied MIF = 0.00 dB Average Value of Peak (interpolated) = 89.1 V/m



0 dB = 89.26 V/m = 39.01 dBV/m

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DUT: CD3500V3 - SN1005

Type: CD3500V3 Serial: 1005

Communication System: CW; Frequency: 3500 MHz;

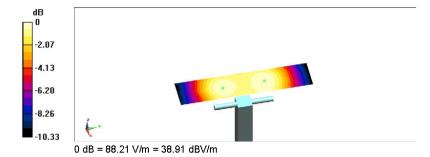
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- · Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

3500 MHz / 100mW HAC Dipole Validation at 15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 40.13 V/m; Power Drift = 0.10 dB Applied MIF = 0.00 dB Average Value of Peak (interpolated) = 87.9 V/m



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DUT: A3LSMG996U

Type: Portable Handset Serial: 0516M Backlight off Duty Cycle: 1:8

Communication System: CDMA; Frequency: 820.1 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

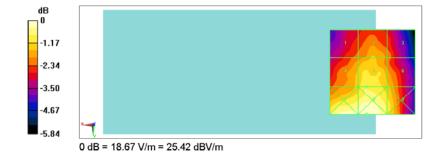
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- · Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

Secondary Cellular CDMA Mid Channel/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 15.66 V/m; Power Drift = 0.12 dB
Applied MIF = 3.05 dB
RF audio interference level = 24.59 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
23.33 dBV/m	23.92 dBV/m	23.42 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
24.09 dBV/m	24.59 dBV/m	24.05 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
25.31 dBV/m	25.42 dBV/m	24.58 dBV/m



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DUT: A3LSMG996U

Type: Portable Handset Serial: 0516M Backlight off Duty Cycle: 1:8

Communication System: CDMA; Frequency: 1908.75 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

PCS CDMA High Channel/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 6.106 V/m; Power Drift = -0.19 dB
Applied MIF = 3.05 dB
RF audio interference level = 17.94 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
20.44 dBV/m	20.81 dBV/m	20.05 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
17.57 dBV/m	17.94 dBV/m	17.16 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
16.32 dBV/m	16.21 dBV/m	15.76 dBV/m



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DUT: A3LSMG996U

Type: Portable Handset Serial: 0516M Backlight off Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 824.2 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

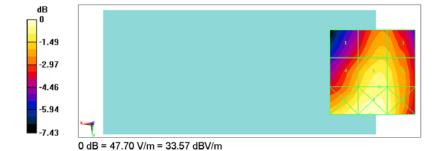
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- · Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

GSM850 Low Channel/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 39.37 V/m; Power Drift = 0.15 dB
Applied MIF = 3.54 dB
RF audio interference level = 32.86 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
30.58 dBV/m	32.01 dBV/m	31.9 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
32 dBV/m	32.86 dBV/m	32.65 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
33.22 dBV/m	33.57 dBV/m	32.97 dBV/m



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DUT: A3LSMG996U

Type: Portable Handset Serial: 0516M Backlight off Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 1850.2 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- · Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

GSM1900 Low Channel/Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 8.262 V/m; Power Drift = 0.16 dB
Applied MIF = 3.55 dB
RF audio interference level = 23.88 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
27.63 dBV/m	28.04 dBV/m	26.87 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
22.28 dBV/m	23.11 dBV/m	23.07 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
23.88 dBV/m	23.79 dBV/m	22.83 dBV/m



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DUT: A3LSMG996U

Type: Portable Handset Serial: 0516M Backlight off Duty Cycle: 1:4.67

Communication System: LTE TDD41; Frequency: 2636.5 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

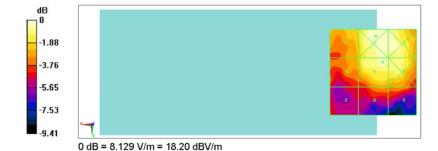
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

LTE TDD Band 41 (PC3), 20MHz BW, Mid High Channel, UL-DL 2, 64QAM, 1RB, 0RB Offset Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 8.552 V/m; Power Drift = 0.03 dB Applied MIF = 1.54 dB RF audio interference level = 17.90 dBV/m Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
16.29 dBV/m	18.2 dBV/m	18.06 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
15.92 dBV/m	17.9 dBV/m	17.6 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
14.43 dBV/m	15.42 dBV/m	15.29 dBV/m



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DUT: A3LSMG996U

Type: Portable Handset Serial: 0516M Backlight off Duty Cycle: 1:4.67

Communication System: LTE TDD41; Frequency: 2636.5 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

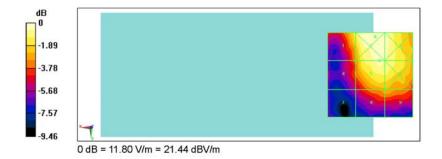
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

LTE TDD Band 41 (PC2), 10MHz BW, Mid High Channel, UL-DL 2, 16QAM, 1RB, 0RB Offset Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 10.95 V/m; Power Drift = -0.05 dB Applied MIF = 1.44 dB RF audio interference level = 20.93 dBV/m Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
20.09 dBV/m	21.44 dBV/m	21.12 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
18.28 dBV/m	20.93 dBV/m	20.82 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
		18.9 dBV/m



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DUT: A3LSMG996U

Type: Portable Handset Serial: 6134M Backlight off Duty Cycle: 1:4.67

Communication System: LTE Band 48; Frequency: 3695 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

LTE TDD Band 48, 10MHz BW, High Channel, UL-DL 2, 64QAM, 1RB, 0RB Offset Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 11.26 V/m; Power Drift = -0.18 dB
Applied MIF = 1.51 dB
RF audio interference level = 21.70 dBV/m
Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
16.89 dBV/m	18 dBV/m	18.06 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
19.64 dBV/m	21.7 dBV/m	21.55 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
23.86 dBV/m	22.39 dBV/m	22.15 dBV/m



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DUT: A3LSMG996U

Type: Portable Handset Serial: 0516M Backlight off Duty Cycle: 1:4

Communication System: n41; Frequency: 2593 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

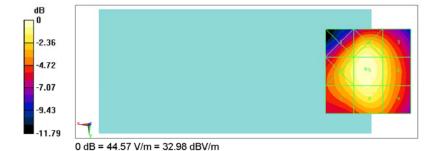
- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- · Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

NR TDD n41 (PC2), 100MHz, Mid Channel, Ant I, DFT-s-OFDM, QPSK, 1RB, 1RB Offset Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm
Device Reference Point: 0, 0, -6.3 mm
Reference Value = 62.26 V/m; Power Drift = 0.09 dB
Applied MIF = 1.39 dB
RF audio interference level = 32.98 dBV/m
Emission category: M3

MIF scaled E-field

Grid 1 M3	Grid 2 M3	Grid 3 M3
31.03 dBV/m	32.48 dBV/m	30.97 dBV/m
Grid 4 M3	Grid 5 M3	Grid 6 M3
31.9 dBV/m	32.98 dBV/m	31.45 dBV/m
Grid 7 M3	Grid 8 M3	Grid 9 M3
31.24 dBV/m	32.33 dBV/m	31.06 dBV/m



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DUT: A3LSMG996U

Type: Portable Handset Serial: 6134M Backlight off Duty Cycle: 1:4

Communication System: n77; Frequency: 3750 MHz;

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY5 Configuration:

- Probe: EF3DV3 SN4035; Calibrated: 1/16/2019;
- · Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn665; Calibrated: 2/12/2020
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, Version 52.10 (0);

NR TDD n77, 100MHz, Low Channel, DFT-s-OFDM, π /2-BPSK, 1RB, 1RB Offset Hearing Aid Compatibility Test (101x101x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 18.84 V/m; Power Drift = -0.02 dB

Applied MIF = 1.40 dB

RF audio interference level = 26.59 dBV/m

Emission category: M4

MIF scaled E-field

Grid 1 M4	Grid 2 M4	Grid 3 M4
21.38 dBV/m	22.97 dBV/m	23.25 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
24.23 dBV/m	26.58 dBV/m	26.59 dBV/m
Grid 7 M4	Grid 8 M4	Grid 9 M4
28.16 dBV/m	27.07 dBV/m	26.93 dBV/m



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CALIBRATION CERTIFICATES 15.

The following pages include the probe calibration used to evaluate HAC for the DUT.

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Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





С

Schweizerischer Kalibrierdienst Service suisse d'étalonnage Servizio svizzero di taratura Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 0108

Client

PC Test

Certificate No: EF3-4035_Jan19/2

CALIBRATION CERTIFICATE (Replacement of No: EF3-4035_Jan19)

Object

EF3DV3- SN:4035

Calibration procedure(s)

QA CAL-02.v9, QA CAL-25.v7

Calibration procedure for E-field probes optimized for close near field

evaluations in air

Calibration date:

January 16, 2019

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter NRP	SN: 104778	04-Apr-18 (No. 217-02672/02673)	Apr-19
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672)	Apr-19
Power sensor NRP-Z91	SN: 103245	04-Apr-18 (No. 217-02673)	Apr-19
Reference 20 dB Attenuator	SN: S5277 (20x)	04-Apr-18 (No. 217-02682)	Apr-19
DAE4	SN: 789	14-Jan-19 (No. DAE4-789_Jan19)	Jan-20
Reference Probe ER3DV6	SN: 2328	09-Oct-18 (No. ER3-2328_Oct18)	Oct-19
Secondary Standards	ID	Check Date (in house)	Scheduled Check
Power meter E4419B	SN: GB41293874	06-Apr-16 (in house check Jun-18)	In house check: Jun-20
Power sensor E4412A	SN: MY41498087	06-Apr-16 (in house check Jun-18)	In house check: Jun-20
Power sensor E4412A	SN: 000110210	06-Apr-16 (in house check Jun-18)	In house check; Jun-20
RF generator HP 8648C	SN: US3642U01700	04-Aug-99 (in house check Jun-18)	In house check: Jun-20
Network Analyzer E8358A	SN: US41080477	31-Mar-14 (in house check Oct-18)	In house check: Oct-19

	Name	Function	Signature	
Calibrated by:	Manu Seitz	Laboratory Technician	A COLOR	
Approved by:	Katja Pokovic	Technical Manager	AM	-

Issued: February 11, 2019

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: EF3-4035_Jan19/2

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Calibration Laboratory of

Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kallbrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Glossary:

NORMx,y,z sensitivity in free space DCP diode compression point

CF crest factor (1/duty_cycle) of the RF signal modulation dependent linearization parameters En incident E-field orientation normal to probe axis Ep incident E-field orientation parallel to probe axis

Polarization ϕ ϕ rotation around probe axis

Polarization 9 9 rotation around an axis that is in the plane normal to probe axis (at measurement center),

i.e., 9 = 0 is normal to probe axis

Connector Angle information used in DASY system to align probe sensor X to the robot coordinate system

Calibration is Performed According to the Following Standards:

 a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005

b) CTIA Test Plan for Hearing Aid Compatibility, Rev 3.1.1, May 2017

Methods Applied and Interpretation of Parameters:

NORMx, y, z: Assessed for E-field polarization 9 = 0 for XY sensors and 9 = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).

- NORM(f)x,y,z = NORMx,y,z * frequency_response (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z; Dx,y,z; VRx,y,z: A, B, C, D are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no uncertainty required).

Certificate No: EF3-4035_Jan19/2

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DASY/EASY - Parameters of Probe: EF3DV3 - SN:4035

Basic Calibration Parameters

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm $(\mu V/(V/m)^2)$	0.90	0.74	1.20	± 10.1 %
DCP (mV) ^B	96.8	98.5	95.3	

Calibration results for Frequency Response (30 MHz = 6 GHz)

Frequency MHz	Target E-Field V/m	Measured E-field (En) V/m	Deviation E-normal in %	Measured E-field (Ep) V/m	Deviation E-normal in %	Unc (k=2) %
30	77.3	76.8	-0.6%	77.3	0.1%	± 5.1 %
100	77.3	78.2	1.2%	77.8	0.7%	± 5.1 %
450	77.1	78.2	1.5%	77.8	0.9%	± 5.1 %
600	77.1	77.8	0.9%	77.5	0.5%	± 5.1 %
750	77.3	77.7	0.5%	77.2	-0.1%	± 5.1 %
1800	140.3	136.9	-2.4%	137.2	-2.2%	± 5.1 %
2000	133.0	129.4	-2.8%	129.4	-2.7%	± 5.1 %
2200	124.8	121.5	-2.7%	122.7	-1.7%	± 5.1 %
2500	123.7	120.7	-2.4%	121.9	-1.5%	± 5.1 %
3000	78.8	74.8	-5.0%	76.1	-3.5%	± 5.1 %
3500	256.3	248.1	-3.2%	246.0	-4.0%	± 5.1 %
3700	249.7	239.2	-4.2%	239.0	-4.3%	± 5.1 %
5200	50.7	50.7	-0.1%	51.2	0.9%	± 5.1 %
5500	49.6	48.9	-1.5%	48.7	-1.9%	± 5.1 %
5800	48.9	49.1	0.4%	49.3	0.8%	± 5.1 %

Calibration Results for Modulation Response

UID	Communication System Name		A dB	B dB√μV	С	D dB	VR mV	Max dev.	Unc ^t (k=2)
0	CW	X	0.0	0.0	1.0	0.00	141.5	+ 3.3 %	± 4.7 %
		Y	0.0	0.0	1.0		125.6		
		Υ	0.0	0.0	1.0		125.1		

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Certificate No: EF3-4035_Jan19/2

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B Numerical linearization parameter: uncertainty not required.
E Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the

DASY/EASY - Parameters of Probe: EF3DV3 - SN:4035

Sensor Frequency Model Parameters

	Sensor X	Sensor Y	Sensor Z
Frequency Corr. (LF)	0.28	0.21	5.68
Frequency Corr. (HF)	2.82	2.82	2.82

Other Probe Parameters

Sensor Arrangement	Rectangular
Connector Angle (°)	57.9
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	12 mm
Tip Length	25 mm
Tip Diameter	4 mm
Probe Tip to Sensor X Calibration Point	1.5 mm
Probe Tip to Sensor Y Calibration Point	1.5 mm
Probe Tip to Sensor Z Calibration Point	1.5 mm

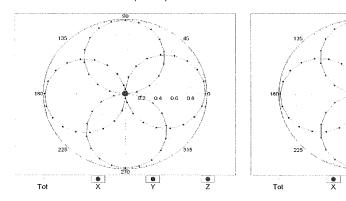
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Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$

f=600 MHz,TEM,0°

f=1800 MHz,R22,0°

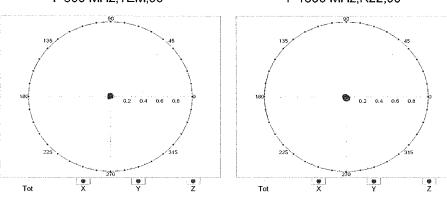


Receiving Pattern (ϕ), $9 = 90^{\circ}$

f=600 MHz,TEM,90°

f=1800 MHz,R22,90°

⊗ Z.

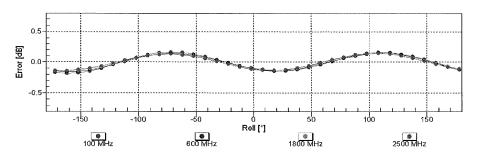


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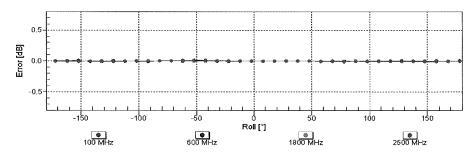
FCC ID: A3LSMG996U	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Approved by: Quality Manager
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Receiving Pattern (ϕ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

Receiving Pattern (ϕ), $\vartheta = 90^{\circ}$



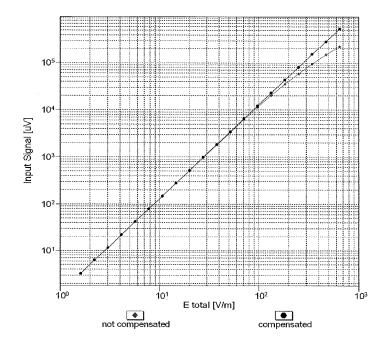
Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

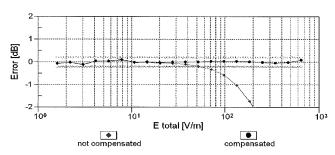
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Dynamic Range f(E-field) (TEM cell, f = 900 MHz)





Uncertainty of Linearity Assessment: ± 0.6% (k=2)

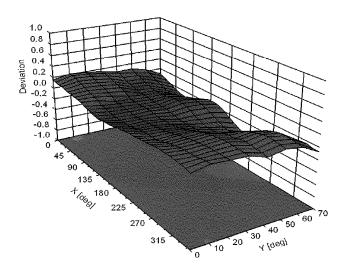
Certificate No: EF3-4035_Jan19/2

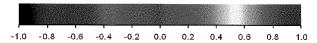
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Deviation from Isotropy in Air

Error (ϕ , ϑ), f = 900 MHz





Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

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Calibration Laboratory of Schmid & Partner

Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Multilateral Agreement for the recognition of calibration certificates

Client PC Test

Accreditation No.: SCS 0108

Certificate No: CD835V3-1003_Feb19

Object	CD835V3 - SN;	1003			
Calibration procedure(s)	QA CAL-20.v7 Calibration Procedure for Validation Sources in air y19/2014				
Calibration date:	February 19, 2019				
The measurements and the unce	ertainties with confidence partainties with confidence partainties.	ional standards, which realize the physical un probability are given on the following pages are ry facility: environment temperature (22 \pm 3)%	nd are part of the certificate.		
Primary Standards	ID#	Cal Date (Certificate No.)	Ontroduction of the control		
Power meter NRP	SN: 104778	04-Apr-18 (No. 217-02672/02673)	Scheduled Calibration		
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672)	Apr-19		
Power sensor NRP-Z91	SN: 103245	04-Apr-18 (No. 217-02673)	Apr-19		
Reference 20 dB Attenuator	SN: 5058 (20k)	04-Apr-18 (No. 217-02682)	Apr-19		
Type-N mismatch combination	SN: 5047.2 / 06327		Apr-19		
Probe EF3DV3	SN: 4013	04-Apr-18 (No. 217-02683)	Apr-19		
	SN: 781	03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19)	Jan-20 Jan-20		
DAE4	1014.701	- ,	Jan-20		
DAE4 Secondary Standards	ID #	Check Date (in house)			
		Check Date (in house)	Scheduled Check		
Secondary Standards Power meter Agilent 4419B	ID#	Check Date (in house) 09-Oct-09 (in house check Oct-17)	Scheduled Check In house check: Oct-20		
Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A	ID # SN: GB42420191	Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17)	Scheduled Check In house check: Oct-20 In house check: Oct-20		
Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A	ID # SN: GB42420191 SN: US38485102	Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17) 09-Oct-09 (in house check Oct-17)	Scheduled Check In house check: Oct-20 In house check: Oct-20 In house check: Oct-20		
Secondary Standards	ID # SN: GB42420191 SN: US38485102 SN: US37295597	Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17)	Scheduled Check In house check: Oct-20 In house check: Oct-20		
Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011	Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17) 09-Oct-09 (in house check Oct-17) 27-Aug-12 (in house check Oct-17)	Scheduled Check In house check: Oct-20 In house check: Oct-20 In house check: Oct-20 In house check: Oct-20 In house check: Oct-19		
Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011 SN: US41080477	Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17) 09-Oct-09 (in house check Oct-17) 27-Aug-12 (in house check Oct-17) 31-Mar-14 (in house check Oct-18)	Scheduled Check In house check: Oct-20 In house check: Oct-20 In house check: Oct-20 In house check: Oct-20		
Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06 Network Analyzer HP 8358A	ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011 SN: US41080477 Name	Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17) 09-Oct-09 (in house check Oct-17) 27-Aug-12 (in house check Oct-17) 31-Mar-14 (in house check Oct-18) Function	Scheduled Check In house check: Oct-20		
Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06 Network Analyzer HP 8358A	ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011 SN: US41080477 Name	Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17) 09-Oct-09 (in house check Oct-17) 27-Aug-12 (in house check Oct-17) 31-Mar-14 (in house check Oct-18) Function	Scheduled Check In house check: Oct-20		

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Calibration Laboratory of Schmid & Partner **Engineering AG**

Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst Service suisse d'étalonnage Servizio svizzero di taratura Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

References

ANSI-C63.19-2011 [1] American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids,

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 15 mm above the top metal edge of the dipole arms
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.2
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	835 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 835 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	105.2 V/m = 40.44 dBV/m
Maximum measured above low end	100 mW input power	105.1 V/m = 40.43 dBV/m
Averaged maximum above arm	100 mW input power	105.2 V/m ± 12.8 % (k=2)

Appendix (Additional assessments outside the scope of SCS 0108)

Antenna Parameters

Frequency	Return Loss	Impedance
800 MHz	17.6 dB	40.4 Ω - 7.2 jΩ
835 MHz	25.8 dB	52.2 Ω + 4.7 jΩ
880 MHz	16.9 dB	62.1 Ω - 10.5 jΩ
900 MHz	16.9 dB	52.2 Ω - 14.6 Ω
945 MHz	21.6 dB	51.8 Ω + 8.3 jΩ

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

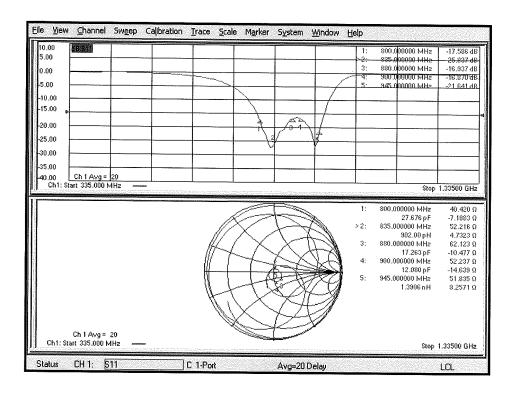
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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Impedance Measurement Plot



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DASY5 E-field Result

Date: 19.02.2019

Test Laboratory: SPEAG Lab2

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: CD835V3 - SN: $1003\,$

Communication System: UID 0 - CW; Frequency: 835 MHz Medium parameters used: $\sigma = 0$ S/m, $\epsilon_r = 1$; $\rho = 0$ kg/m³ Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 835 MHz; Calibrated: 03.01.2019
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 09.01.2019
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.2(1495); SEMCAD X 14.6.12(7450)

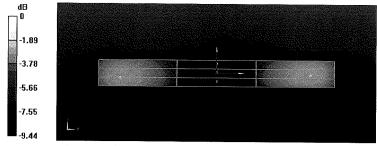
Dipole E-Field measurement @ 835MHz/E-Scan - 835MHz d=15mm/Hearing Aid Compatibility Test (41x361x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm Device Reference Point: 0, 0, -6.3 mm Reference Value = 127.3 V/m; Power Drift = 0.04 dB Applied MIF = 0.00 dBRF audio interference level = 40.44 dBV/m

Emission category: M3

MIF scaled E-field

Grid 1 M4	Grid 2 M3	Grid 3 M3
39.75 dBV/m	40.43 dBV/m	40.43 dBV/m
Grid 4 M4	Grid 5 M4	Grid 6 M4
35.35 dBV/m	35.75 dBV/m	35.73 dBV/m
Grid 7 M3	Grid 8 M3	Grid 9 M3
40.15 dBV/m	40.44 dBV/m	40.36 dBV/m



0 dB = 105.2 V/m = 40.44 dBV/m

Certificate No: CD835V3-1003_Feb19

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Calibration Laboratory of

Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





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Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 0108

Client

PC Test

Certificate No: CD1880V3-1137_Feb19

Object	CD1880V3 - SN: 1137			
Calibration procedure(s)	QA CAL-20.v7 Calibration Procedure for Validation Sources in air			JO= 3/19/20
Calibration date:	February 19, 2019			
The measurements and the unc	ertainties with confidence p	ional standards, which realize the physical un probability are given on the following pages ar pry facility: environment temperature (22 \pm 3)°0	nd are part of the certificate.	
Primary Standards	ID #	0-10-4-40-40-40		
Power meter NRP	SN: 104778	Cal Date (Certificate No.)	Scheduled Calibration	
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672/02673)	Apr-19	
Power sensor NRP-Z91	SN: 103244 SN: 103245	04-Apr-18 (No. 217-02672)	Apr-19	
	014. 100245	04-Apr-18 (No. 217-02673)		
Reference 20 dB Attenueter	ONL FORO (DOL)		Apr-19	
	SN: 5058 (20k)	04-Apr-18 (No. 217-02682)	Apr-19 Apr-19	
Type-N mismatch combination	SN: 5047.2 / 06327	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683)	•	
Type-N mismatch combination Probe EF3DV3	SN: 5047,2 / 06327 SN: 4013	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19)	Apr-19	
Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4	SN: 5047.2 / 06327	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683)	Apr-19 Apr-19	
Type-N mismatch combination Probe EF3DV3	SN: 5047,2 / 06327 SN: 4013	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19)	Apr-19 Apr-19 Jan-20 Jan-20	
Fype-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards	SN: 5047.2 / 06327 SN: 4013 SN: 781	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19) Check Date (in house)	Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check	
Type-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards Power meter Aglient 4419B	SN: 5047.2 / 06327 SN: 4013 SN: 781	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19) Check Date (in house) 09-Oct-09 (in house check Oct-17)	Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20	
Type-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A	SN: 5047.2 / 06327 SN: 4013 SN: 781 ID # SN: GB42420191 SN: US38485102	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19) Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17)	Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20 In house check: Oct-20	
Type-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A	SN: 5047.2 / 06327 SN: 4013 SN: 781 ID # SN: GB42420191 SN: US38485102 SN: US37295597	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19) Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17) 09-Oct-09 (in house check Oct-17)	Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20 In house check: Oct-20 In house check: Oct-20	
Fype-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	SN: 5047.2 / 06327 SN: 4013 SN: 781 ID # SN: GB42420191 SN: US38485102	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19) Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17)	Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20 In house check: Oct-20	
Type-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06 Metwork Analyzer HP 8358A	SN: 5047.2 / 06327 SN: 4013 SN: 781 ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011 SN: US41080477	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19) Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17) 27-Aug-12 (in house check Oct-17) 31-Mar-14 (in house check Oct-18) Function	Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20 In house check: Oct-20 In house check: Oct-20 In house check: Oct-20	
Type-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards Power meter Agilent 4419B Fower sensor HP E4412A Fower sensor HP 8482A UF generator R&S SMT-06	SN: 5047.2 / 06327 SN: 4013 SN: 781 ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011 SN: US41080477	04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19) Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17) 09-Oct-09 (in house check Oct-17) 27-Aug-12 (in house check Oct-17) 31-Mar-14 (in house check Oct-18)	Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20 In house check: Oct-20 In house check: Oct-20 In house check: Oct-20 In house check: Oct-19	

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Calibration Laboratory of

Schmid & Partner **Engineering AG** Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst S Service suisse d'étalonnage C Servizio svizzero di taratura S Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

References

ANSI-C63.19-2011

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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Approved by: PCTEST FCC ID: A3LSMG996U HAC (RF EMISSIONS) TEST REPORT SAMSUNG Quality Manager Filename: Test Dates: DUT Type: Page 78 of 101 1M2009140143-25-R2.A3L 10/12/2020 - 11/13/2020 Portable Handset

Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.10.2
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	1730 MHz ± 1 MHz 1880 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 1730 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	95.0 V/m = 39.55 dBV/m
Maximum measured above low end	100 mW input power	94.9 V/m = 39.55 dBV/m
Averaged maximum above arm	100 mW input power	95.0 V/m ± 12.8 % (k=2)

Maximum Field values at 1880 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	88.9 V/m = 38.98 dBV/m
Maximum measured above low end	100 mW input power	86.6 V/m = 38.75 dBV/m
Averaged maximum above arm	100 mW input power	87.8 V/m ± 12.8 % (k=2)

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Appendix (Additional assessments outside the scope of SCS 0108)

Antenna Parameters

Nominal Frequencies

Frequency	Return Loss	Impedance	
1730 MHz	22.5 dB	$54.4 \Omega + 6.5 j\Omega$	
1880 MHz	21.1 dB	55.9 Ω + 7.2 jΩ	
1900 MHz	21.0 dB	59.0 Ω + 3.6 jΩ	
1950 MHz	27.3 dB	53.0 Ω - 3.3 jΩ	
2000 MHz	20.3 dB	42.4 Ω + 4.8 jΩ	

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

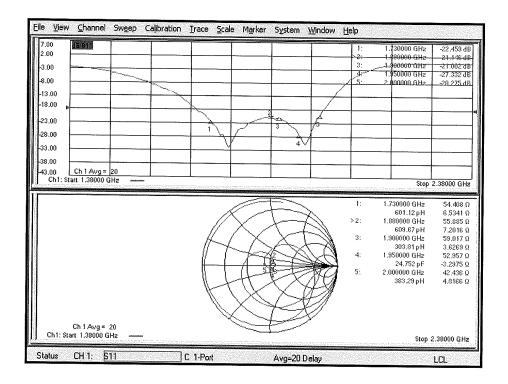
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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Impedance Measurement Plot



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DASY5 E-field Result

Date: 19.02.2019

Test Laboratory: SPEAG Lab2

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: CD1880V3 - SN: 1137

Communication System: UID 0 - CW; Frequency: 1880 MHz, Frequency: 1730 MHz

Medium parameters used: $\sigma = 0$ S/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section
Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 1880 MHz, ConvF(1, 1, 1) @ 1730 MHz; Calibrated: 03.01.2019
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 09.01.2019
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.2(1495); SEMCAD X 14.6.12(7450)

Dipole E-Field measurement @ 1880MHz/E-Scan - 1880MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 151.5 V/m; Power Drift = 0.02 dB

Applied MIF = 0.00 dB

RF audio interference level = 38.98 dBV/m

Emission category: M2

MIF scaled E-field

Grid 1 M2	Grid 2 M2	Grid 3 M2
38.55 dBV/m	38.98 dBV/m	38.93 dBV/m
Grid 4 M2	Grid 5 M2	Grid 6 M2
35.71 dBV/m	35.97 dBV/m	35.96 dBV/m
Grid 7 M2	Grid 8 M2	Grid 9 M2
38.31 dBV/m	38.75 dBV/m	38.73 dBV/m

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FCC ID: A3LSMG996U	PCTEST Proud to be posted to be second	AC (RF EMISSIONS) TEST REPORT	SAMSUNG	Approved by: Quality Manager
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$Dipole\ E-Field\ measurement\ @\ 1880MHz\ /E-Scan\ -\ 1730MHz\ d=15mm/Hearing\ Aid\ Compatibility\ Test\ (41x181x1):$

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 165.0 V/m; Power Drift = 0.03 dB

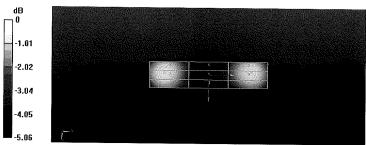
Applied MIF = 0.00 dB

RF audio interference level = 39.55 dBV/m

Emission category: M2

MIF scaled E-field

Grid 1 M2 39.09 dBV/m		Grid 3 M2 39.51 dBV/m
1	Grid 5 M2	
36.57 dBV/m		
Grid 7 M2 39.05 dBV/m		Grid 9 M2 39.53 dBV/m



0 dB = 88.87 V/m = 38.98 dBV/m

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Calibration Laboratory of Schmid & Partner

Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst Service suisse d'étalonnage Servizio svizzero di taratura Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 0108

Client

PC Test

Certificate No: CD2600V3-1012_Feb19

Object	CD2600V3 - SN	: 1012	
Calibration procedure(s)	QA CAL-20.v7 Calibration Proc	edure for Validation Sources in ai	r 10A 3/19/2
Calibration date:	February 19, 20	19	
The measurements and the unce	ertainties with confidence p	ional standards, which realize the physical un robability are given on the following pages an ry facility: environment temperature (22 \pm 3)°C	d are part of the certificate.
Primary Standards	ID#	Cal Date (Certificate No.)	Cobodisted Calibration
Power meter NRP	SN: 104778	04-Apr-18 (No. 217-02672/02673)	Scheduled Calibration Apr-19
Power sensor NRP-Z91	SN: 103244	04-Apr-18 (No. 217-02672)	'
COWER SENSOR NRP-Z91	1014. 100244		Anr-19
Power sensor NRP-Z91 Power sensor NRP-Z91	SN: 103244	,	Apr-19
	1	04-Apr-18 (No. 217-02673)	Apr-19
Power sensor NRP-Z91	SN: 103245	04-Apr-18 (No. 217-02673) 04-Apr-18 (No. 217-02682)	Apr-19 Apr-19
Power sensor NRP-Z91 Reference 20 dB Attenuator	SN: 103245 SN: 5058 (20k)	04-Apr-18 (No. 217-02673) 04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683)	Apr-19 Apr-19 Apr-19
Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination	SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327	04-Apr-18 (No. 217-02673) 04-Apr-18 (No. 217-02682)	Apr-19 Apr-19
Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3	SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013	04-Apr-18 (No. 217-02673) 04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19)	Apr-19 Apr-19 Apr-19 Jan-20 Jan-20
Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards	SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781	04-Apr-18 (No. 217-02673) 04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19)	Apr-19 Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check
Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A	SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781	04-Apr-18 (No. 217-02673) 04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19) Check Date (in house)	Apr-19 Apr-19 Apr-19 Jan-20 Jan-20
Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards Power meter Agiient 4419B Power sensor HP E4412A	SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781	04-Apr-18 (No. 217-02673) 04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19) Check Date (in house) 09-Oct-09 (in house check Oct-17)	Apr-19 Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20
Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781 ID # SN: GB42420191 SN: US38485102	04-Apr-18 (No. 217-02673) 04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19) Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17)	Apr-19 Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20 In house check: Oct-20
Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards Power meter Agilent 4419B	SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781 ID # SN: GB42420191 SN: US38485102 SN: US37295597	04-Apr-18 (No. 217-02673) 04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19) Check Date (in house) 09-Oct-09 (in house check Oct-17) 05-Jan-10 (in house check Oct-17)	Apr-19 Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20 In house check: Oct-20 In house check: Oct-20
Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06 Network Analyzer HP 8358A	SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781 ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011	04-Apr-18 (No. 217-02673) 04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19) Check Date (In house) 09-Oct-09 (In house check Oct-17) 05-Jan-10 (In house check Oct-17) 09-Oct-09 (In house check Oct-17) 27-Aug-12 (In house check Oct-17)	Apr-19 Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20
Power sensor NRP-Z91 Reference 20 dB Attenuator Type-N mismatch combination Probe EF3DV3 DAE4 Secondary Standards Power meter Agilent 4419B Power sensor HP E4412A Power sensor HP 8482A RF generator R&S SMT-06	SN: 103245 SN: 5058 (20k) SN: 5047.2 / 06327 SN: 4013 SN: 781 ID # SN: GB42420191 SN: US38485102 SN: US37295597 SN: 832283/011 SN: US41080477	04-Apr-18 (No. 217-02673) 04-Apr-18 (No. 217-02682) 04-Apr-18 (No. 217-02683) 03-Jan-19 (No. EF3-4013_Jan19) 09-Jan-19 (No. DAE4-781_Jan19) Check Date (in house) 09-Oct-09 (in house check Oct-17) 09-Oct-09 (in house check Oct-17) 27-Aug-12 (in house check Oct-17) 31-Mar-14 (in house check Oct-18)	Apr-19 Apr-19 Apr-19 Jan-20 Jan-20 Scheduled Check In house check: Oct-20

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Calibration Laboratory of Schmid & Partner

Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

References

[1] ANSI-C63.19-2011

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
 (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
 In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
 distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
 figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
 is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
 directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network
 Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was
 eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any
 obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by	the
coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95	5%

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Measurement Conditions

DASY system configuration, as far as not given on page 1

DASY Version	DASY5	V52.10.2
Phantom	HAC Test Arch	
Distance Dipole Top - Probe Center	15 mm	
Scan resolution	dx, dy = 5 mm	
Frequency	2600 MHz ± 1 MHz	
Input power drift	< 0.05 dB	

Maximum Field values at 2600 MHz

E-field 15 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW input power	85.6 V/m = 38.65 dBV/m
Maximum measured above low end	100 mW input power	84.7 V/m = 38.56 dBV/m
Averaged maximum above arm	100 mW input power	85.2 V/m ± 12.8 % (k=2)

Appendix (Additional assessments outside the scope of SCS 0108)

Antenna Parameters

Frequency	Return Loss	Impedance
2450 MHz	20.5 dB	42.7 Ω - 4.8 jΩ
2550 MHz	32.1 dB	48.9 Ω + 2.2 jΩ
2600 MHz	39.6 dB	50.3 Ω + 1.0 jΩ
2650 MHz	30.4 dB	$53.0 \Omega + 0.9 j\Omega$
2750 MHz	20.9 dB	48.9 Ω - 8.9 jΩ

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

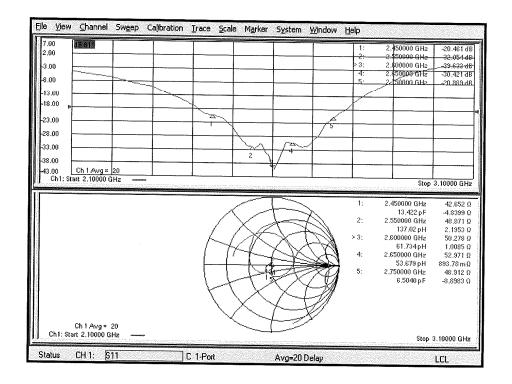
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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Impedance Measurement Plot



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DASY5 E-field Result

Date: 19.02.2019

Test Laboratory: SPEAG Lab2

DUT: HAC Dipole 2600 MHz; Type: CD2600V3; Serial: CD2600V3 - SN: 1012

Communication System: UID 0 - CW ; Frequency: 2600 MHz Medium parameters used: $\sigma=0$ S/m, $\epsilon_r=1$; $\rho=0$ kg/m³ Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 2600 MHz; Calibrated: 03.01.2019
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 09.01.2019
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.2(1495); SEMCAD X 14.6.12(7450)

Dipole E-Field measurement @ 2600MHz - with/E-Scan - 2600MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 62.82 V/m; Power Drift = -0.01 dB

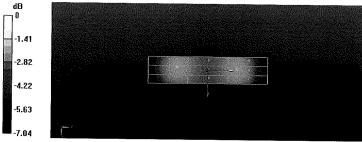
Applied MIF = 0.00 dB

RF audio interference level = 38.65 dBV/m

Emission category: M2

MIF scaled E-field

Grid 1 M2	Grid 2 M2	Grid 3 M2
38.09 dBV/m	38.56 dBV/m	38.54 dBV/m
Grid 4 M2	Grid 5 M2	Grid 6 M2
37.82 dBV/m	38.06 dBV/m	38.02 dBV/m
Grid 7 M2	Grid 8 M2	Grid 9 M2
38.36 dBV/m	38.65 dBV/m	38.56 dBV/m



0 dB = 85.60 V/m = 38.65 dBV/m

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Accreditation No.: SCS 0108

Client

PC Test

Certificate No: CD3500V3-1005 Oct20

CALIBRATION CERTIFICATE Object CD3500V3 - SN: 1005 QA CAL-20.v7 Calibration procedure(s) Calibration Procedure for Validation Sources in air Calibration date: October 20, 2020 This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate. All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%. Calibration Equipment used (M&TE critical for calibration) Primary Standards ID# Cal Date (Certificate No.) Scheduled Calibration Power meter NRP SN: 104778 01-Apr-20 (No. 217-03100/03101) Apr-21 Power sensor NRP-Z91 SN: 103244 01-Apr-20 (No. 217-03100) Apr-21 Power sensor NRP-Z91 SN: 103245 01-Apr-20 (No. 217-03101) Apr-21 Reference 20 dB Attenuator SN: BH9394 (20k) 31-Mar-20 (No. 217-03106) Apr-21 Type-N mismatch combination SN: 310982 / 06327 31-Mar-20 (No. 217-03104) Apr-21 Probe EF3DV3 SN: 4013 31-Dec-19 (No. EF3-4013_Dec19) Dec-20 DAE4 SN: 781 27-Dec-19 (No. DAE4-781_Dec19) Dec-20 Secondary Standards ID# Check Date (in house) Scheduled Check Power meter Agilent 4419B SN: GB42420191 09-Oct-09 (in house check Oct-20) In house check: Oct-23 Power sensor HP E4412A SN: US38485102 05-Jan-10 (in house check Oct-20) In house check: Oct-23 Power sensor HP 8482A SN: US37295597 09-Oct-09 (in house check Oct-20) In house check: Oct-23 RF generator R&S SMT-06 SN: 837633/005 10-Jan-19 (in house check Oct-20) In house check: Oct-23 Network Analyzer Agilent E8358A SN: US41080477 31-Mar-14 (in house check Oct-20) In house check: Oct-21 Name Function Calibrated by: Leif Klysner Laboratory Technician Approved by: Katja Pokovic Technical Manager Issued: October 20, 2020 This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

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Swiss Calibration Service

Accreditation No.: SCS 0108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

References

[1] ANSI-C63.19-2011

American National Standard, Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
 (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other axes.
 In coincidence with the standards [1], the measurement planes (probe sensor center) are selected to be at a
 distance of 15 mm above the top metal edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate. All
 figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector
 is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a
 directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a Vector Network Analyzer.
 The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E-field distribution: E field is measured in the x-y-plane with an isotropic E-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 15 mm (in z) above the metal top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, in the plane above the dipole surface.

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

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 PCTEST
 HAC (RF EMISSIONS) TEST REPORT
 Approved by: Quality Manager

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 DUT Type:

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 10/12/2020 - 11/13/2020
 Portable Handset

Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY5	V52.10.4
HAC Test Arch	
15 mm	
dx, dy = 5 mm	
3500 MHz ± 1 MHz 3900 MHz ± 1 MHz	
< 0.05 dB	
	HAC Test Arch 15 mm dx, dy = 5 mm 3500 MHz ± 1 MHz 3900 MHz ± 1 MHz

Maximum Field values at 3500 MHz

E-field 15 mm above dipole surface	ve dipole surface condition	
Maximum measured above high end	100 mW input power	85.3 V/m = 38.61 dBV/m
Maximum measured above low end	100 mW input power	83.6 V/m = 38.44 dBV/m
Averaged maximum above arm	100 mW input power	84.4 V/m ± 12.8 % (k=2)

Maximum Field values at 3900 MHz

E-field 15 mm above dipole surface	e dipole surface condition	
Maximum measured above high end	100 mW input power	82.0 V/m = 38.28 dBV/m
Maximum measured above low end	100 mW input power	79.9 V/m = 38.05 dBV/m
Averaged maximum above arm	100 mW input power	81.0 V/m ± 12.8 % (k=2)

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Appendix (Additional assessments outside the scope of SCS 0108)

Antenna Parameters

Nominal Frequencies

Frequency	Return Loss	Impedance	
3300 MHz	22.3 dB	$58.2 \Omega + 0.9 jΩ$	
3400 MHz	31.4 dB	52.7 Ω - 0.2 jΩ	
3500 MHz	25.0 dB	55.4 Ω - 2.4 jΩ	
3600 MHz	21.1 dB	49.4 Ω - 8.8 jΩ	
3700 MHz	19.6 dB	41.0 Ω - 3.2 jΩ	

Additional Frequencies

Frequency	Return Loss	Impedance
3900 MHz	17.0 dB	47.7 Ω + 13.8 jΩ

3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

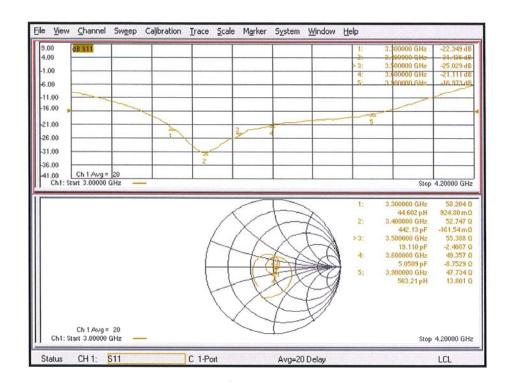
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

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DASY5 E-field Result

Date: 20.10.2020

Test Laboratory: SPEAG Lab2

DUT: HAC Dipole 3500 MHz; Type: CD3500V3; Serial: CD3500V3 - SN: 1005

Communication System: UID 0 - CW; Frequency: 3500 MHz, Frequency: 3900 MHz

Medium parameters used: $\sigma = 0$ S/m, $\varepsilon_r = 1$; $\rho = 0$ kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2011)

DASY52 Configuration:

- Probe: EF3DV3 SN4013; ConvF(1, 1, 1) @ 3500 MHz, ConvF(1, 1, 1) @ 3900 MHz; Calibrated: 31.12.2019
- · Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 27.12.2019
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- DASY52 52.10.4(1527); SEMCAD X 14.6.14(7483)

Dipole E-Field measurement @ 3500MHz/E-Scan - 3500MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 34.56 V/m; Power Drift = 0.03 dB

Applied MIF = 0.00 dB

RF audio interference level = 38.61 dBV/m

Emission category: M2

MIF scaled E-field

Grid 1 M2 38.24 dBV/m		
	Grid 5 M2	
38.41 dBV/m		
Grid 7 M2	Grid 8 M2	Grid 9 M2
38.41 dBV/m	38.6 dBV/m	38.49 dBV/m

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Dipole E-Field measurement @ 3500MHz/E-Scan - 3900MHz d=15mm/Hearing Aid Compatibility Test (41x181x1):

Interpolated grid: dx=0.5000 mm, dy=0.5000 mm

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 31.52 V/m; Power Drift = -0.01 dB

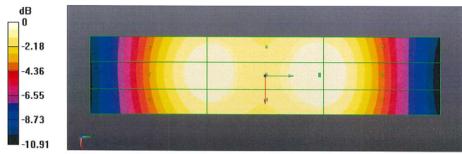
Applied MIF = 0.00 dB

RF audio interference level = $38.28 \ dBV/m$

Emission category: M2

MIF scaled E-field

Grid 1 M2 37.87 dBV/m		
Grid 4 M2 38.11 dBV/m	STATE OF THE PARTY	
Grid 7 M2 38.09 dBV/m		



0 dB = 85.26 V/m = 38.61 dBV/m

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16. CONCLUSION

The measurements, taken in accordance with the procedures provided in the CTIA Test Plan for Hearing Aid Compatibility Rev 3.1.1, May 2017, indicate that the wireless communications device complies with the HAC limits specified in accordance with the ANSI C63.19 Standard and FCC WT Docket No. 01-309 RM-8658. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.

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